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(54) **ORGANIC LIGHT-EMITTING DISPLAY APPARATUS AND METHOD OF MANUFACTURING THE SAME**

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(57) **ABSTRACT**

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An organic light-emitting display device and a method of manufacturing the same, the organic light-emitting display device including pixels including opposing first and second electrodes, and an intermediate layer disposed between the first and second electrodes. The pixels are divided into red, green, and blue sub-pixels. The intermediate layer has a thickness that varies according to the sub-pixels.

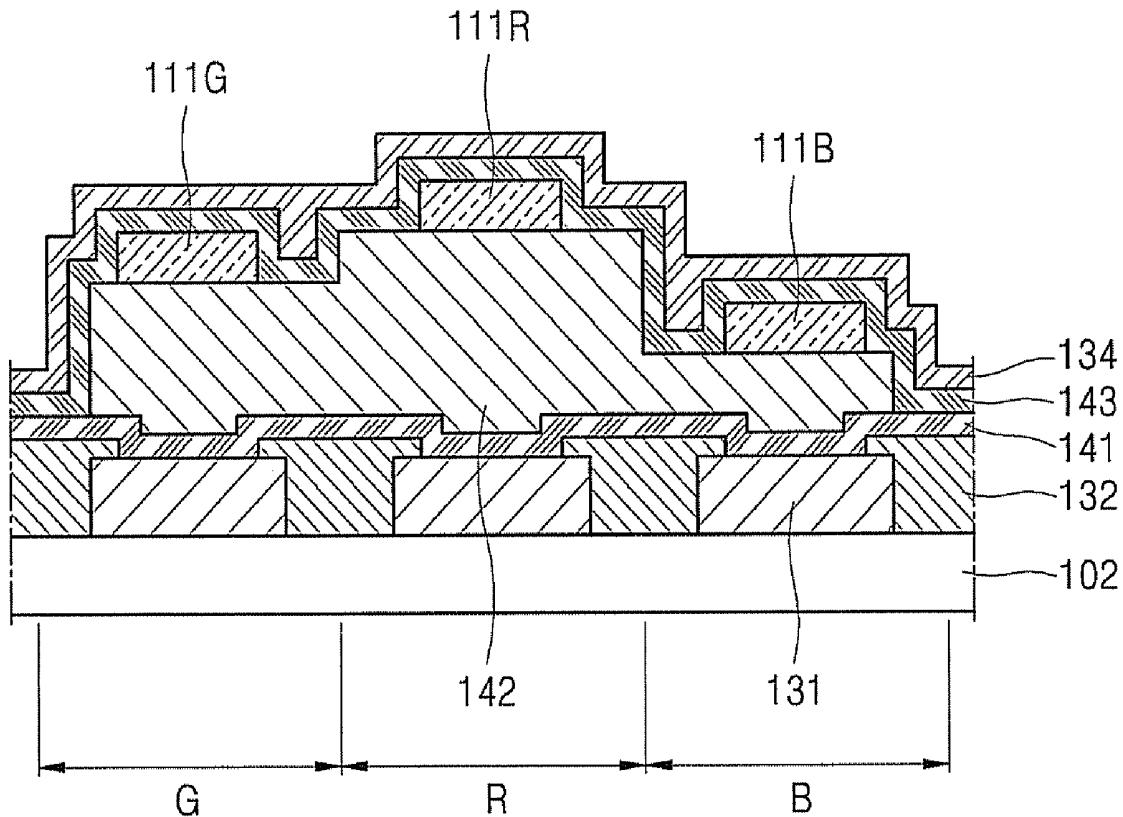


FIG. 1A (Related Art)

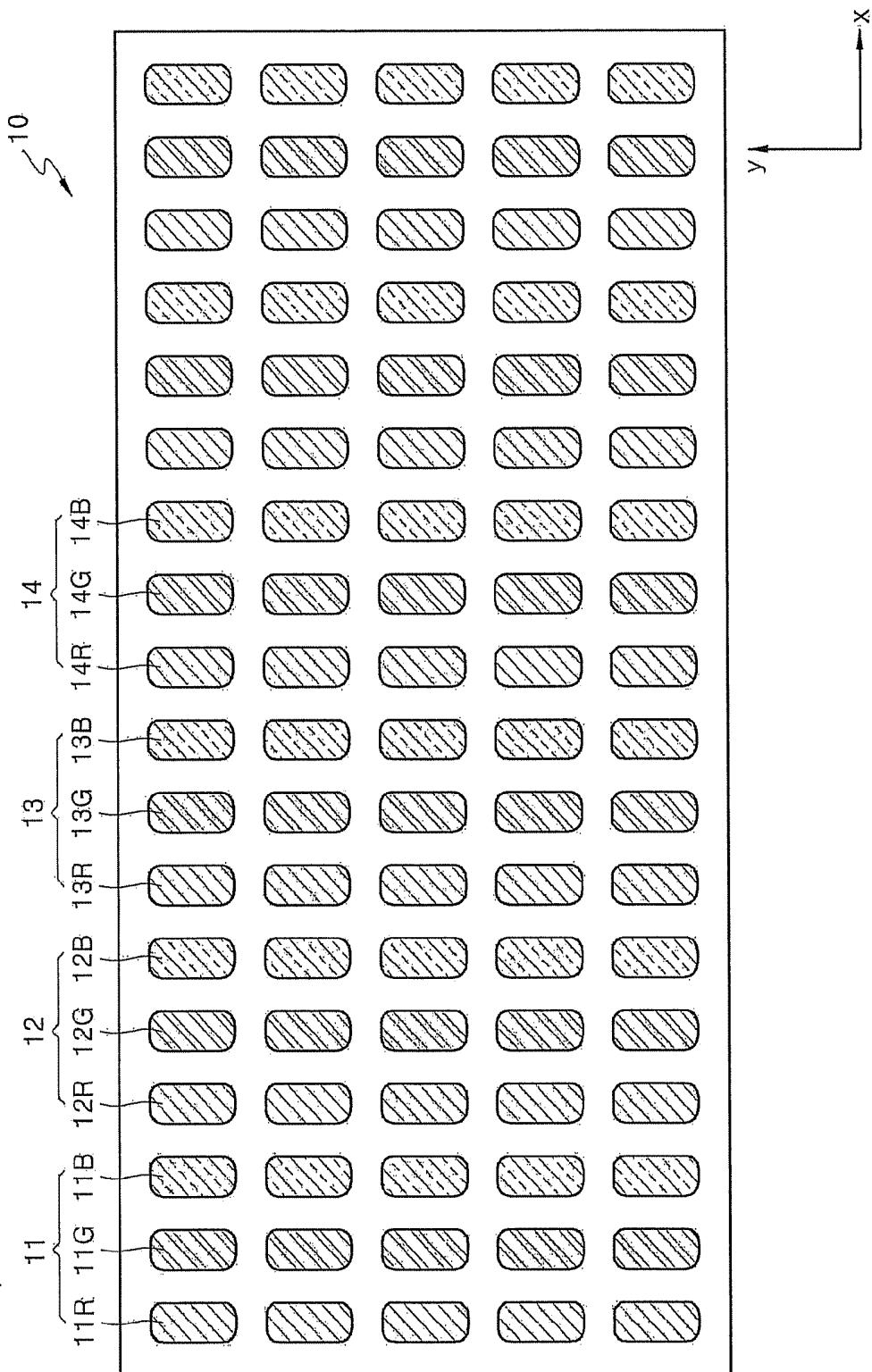


FIG. 1B (Related Art)

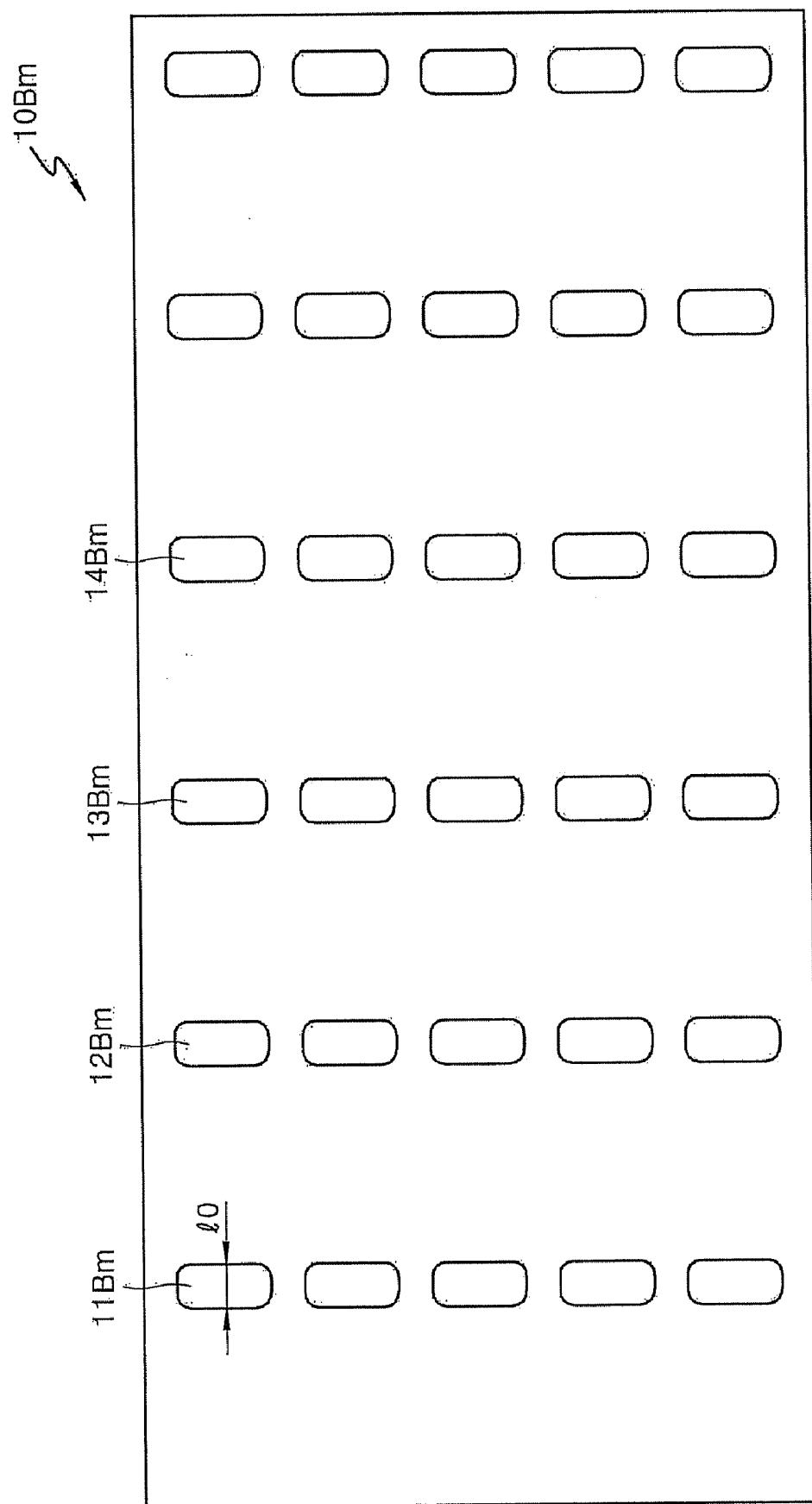


FIG. 2

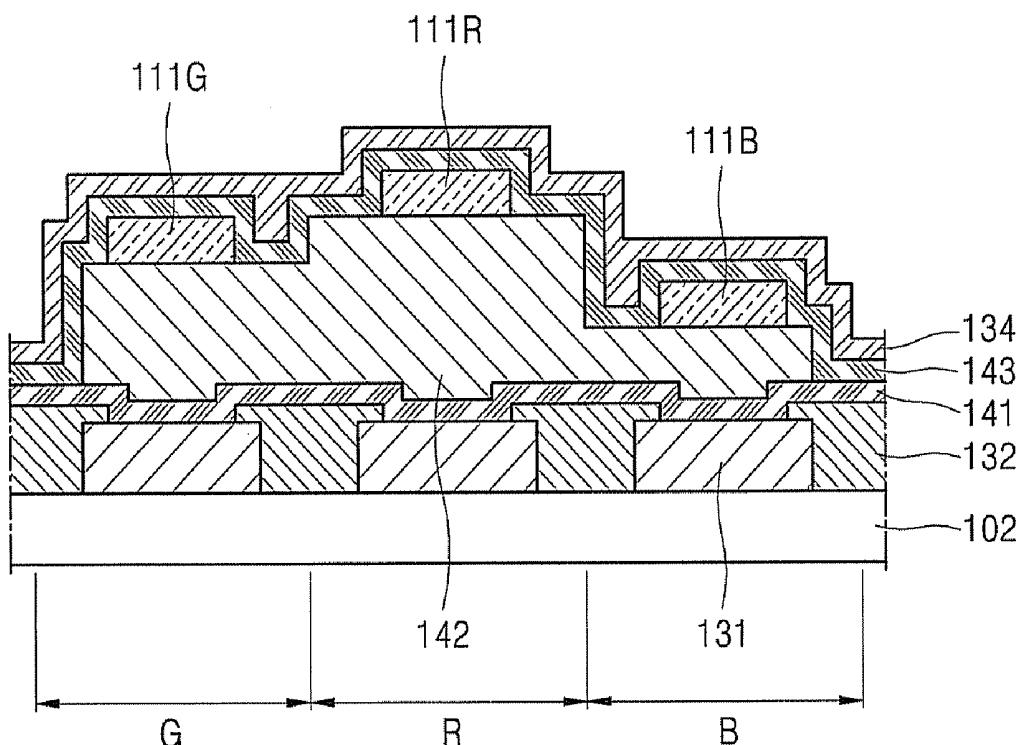


FIG. 3A

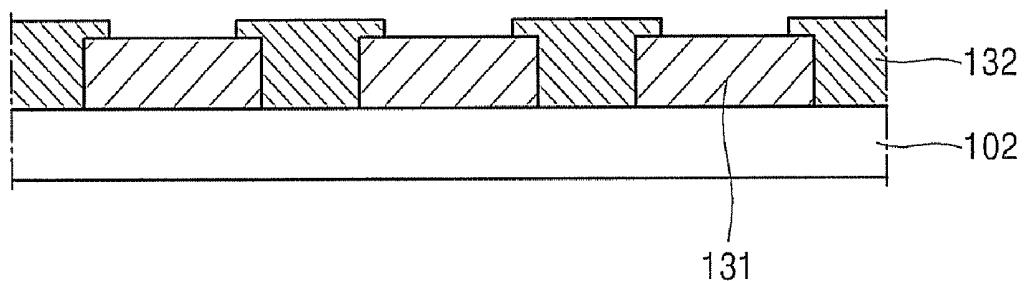


FIG. 3B

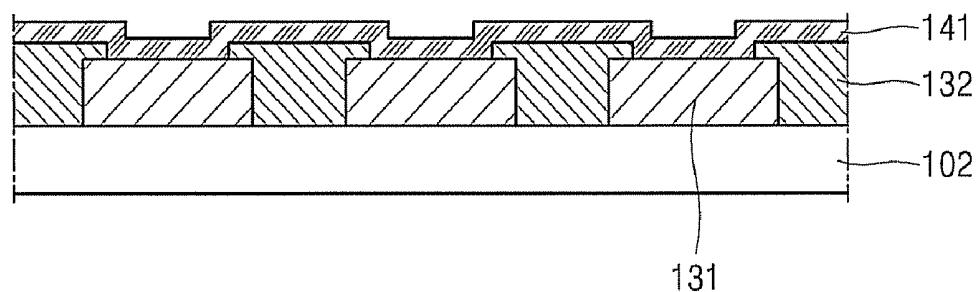


FIG. 3C

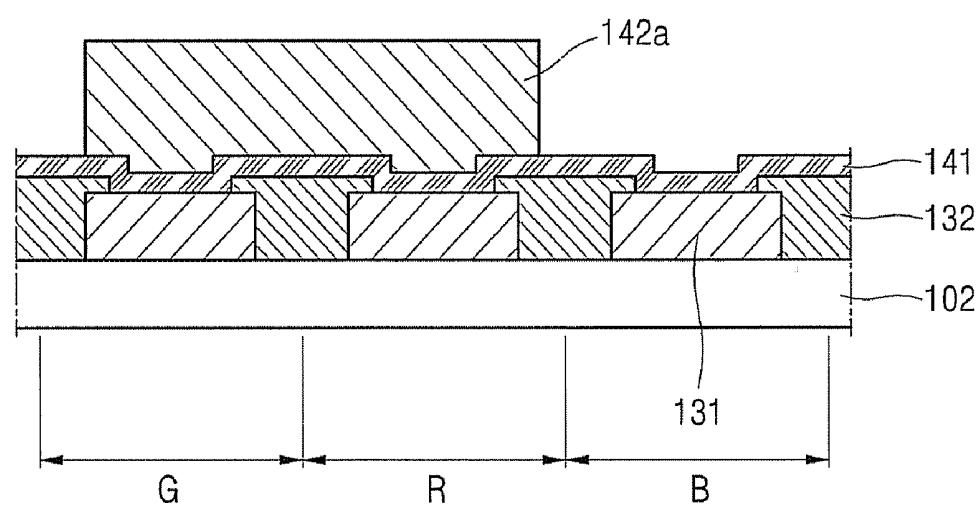
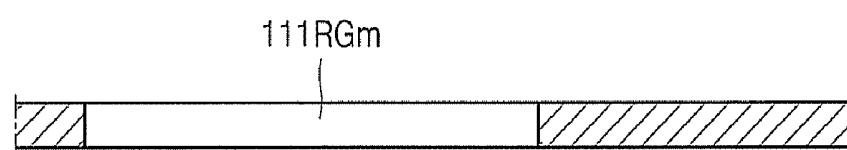


FIG. 3D

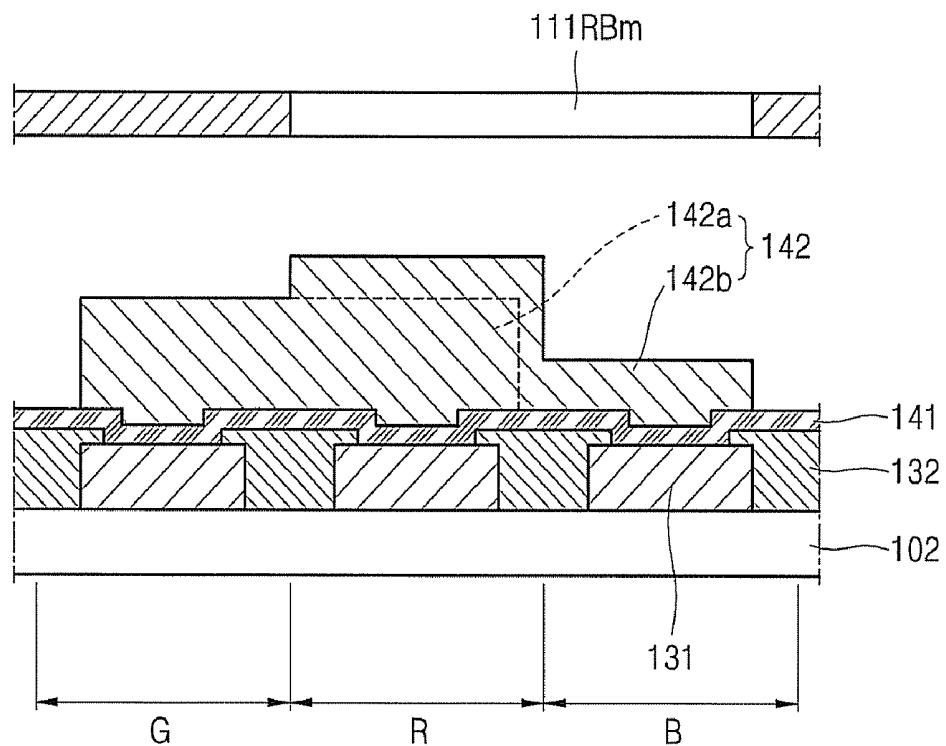


FIG. 3E

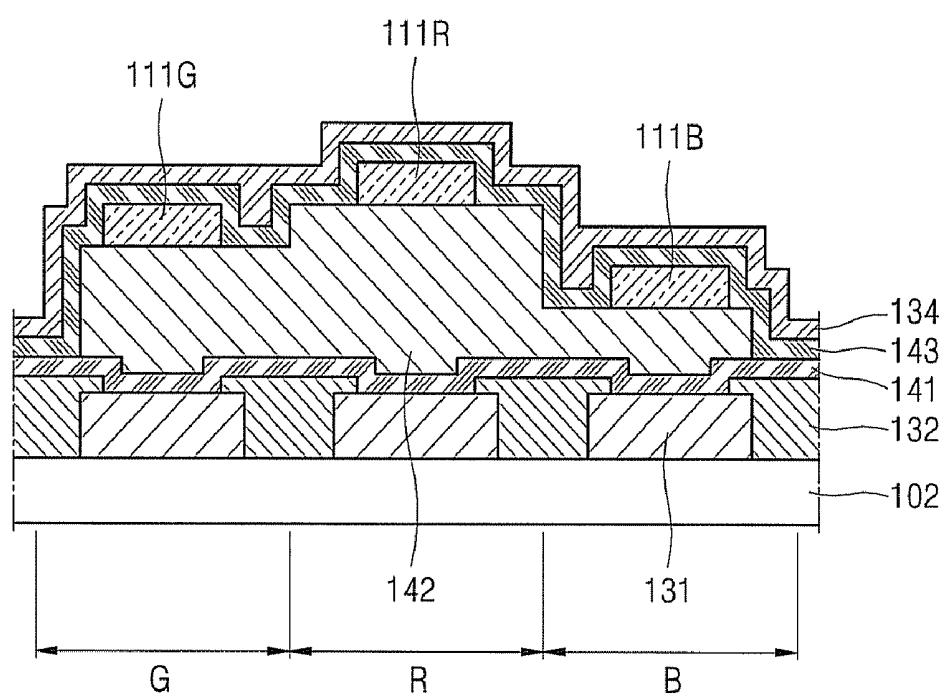


FIG. 4

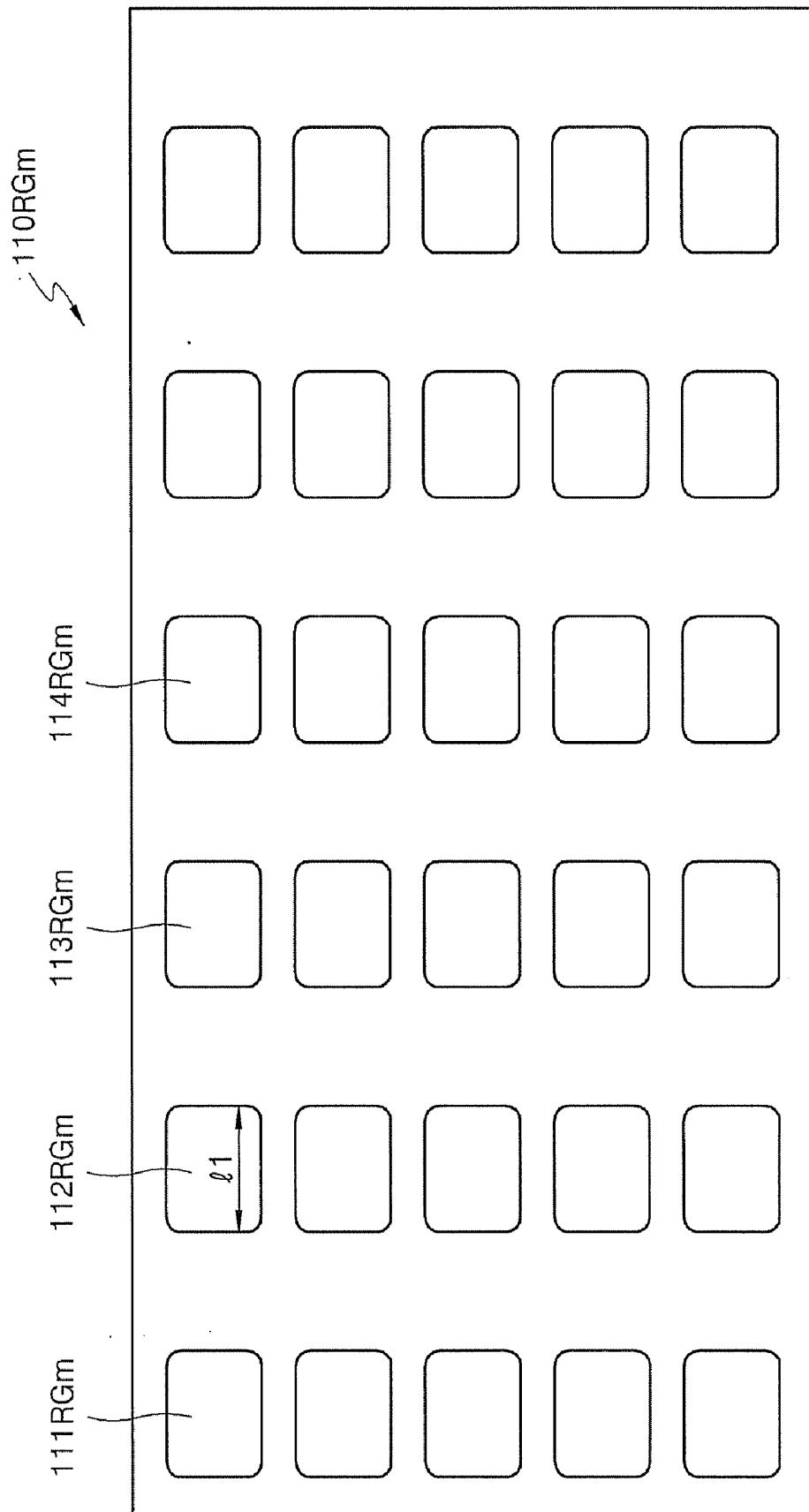


FIG. 5

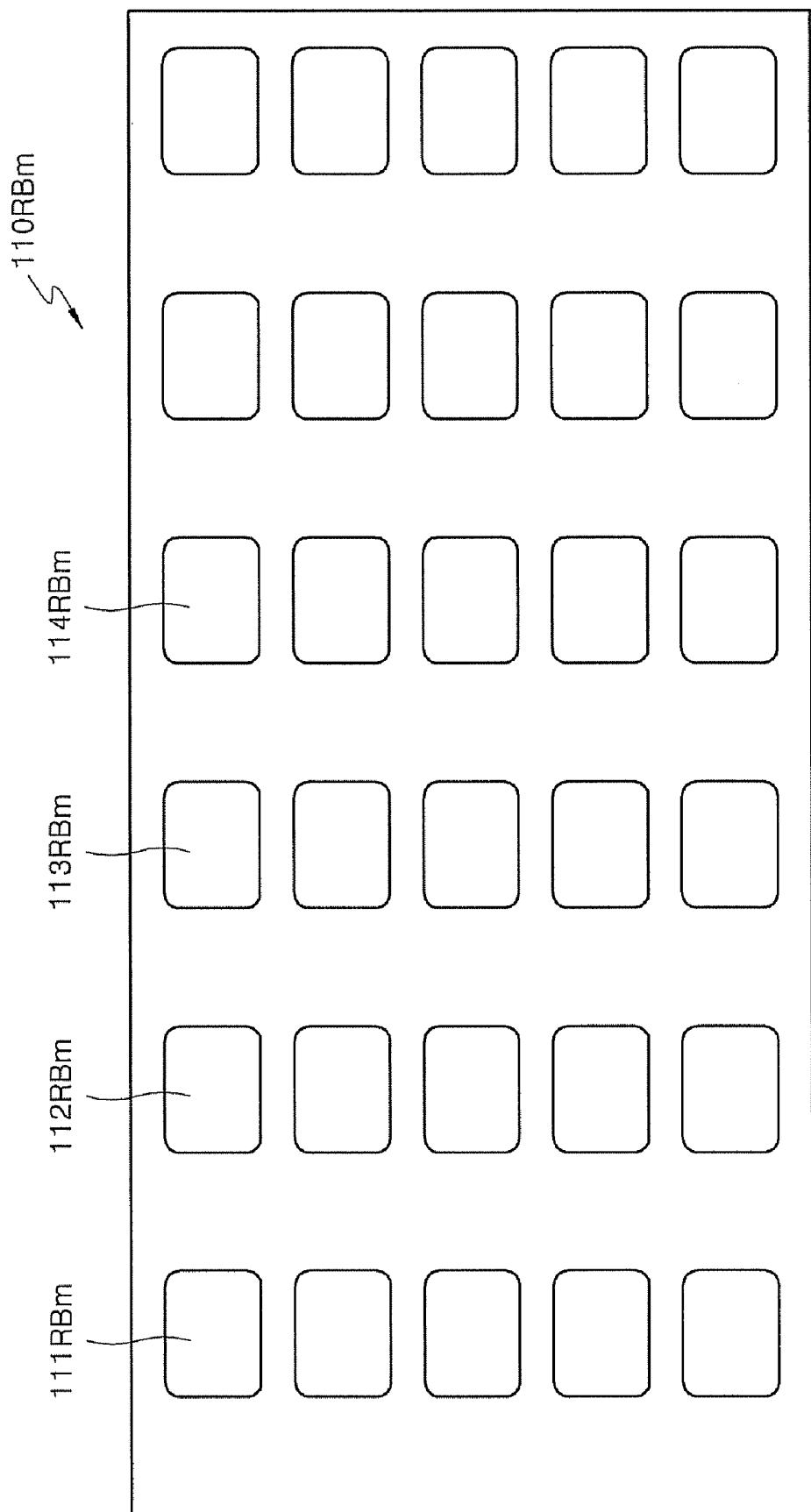


FIG. 6

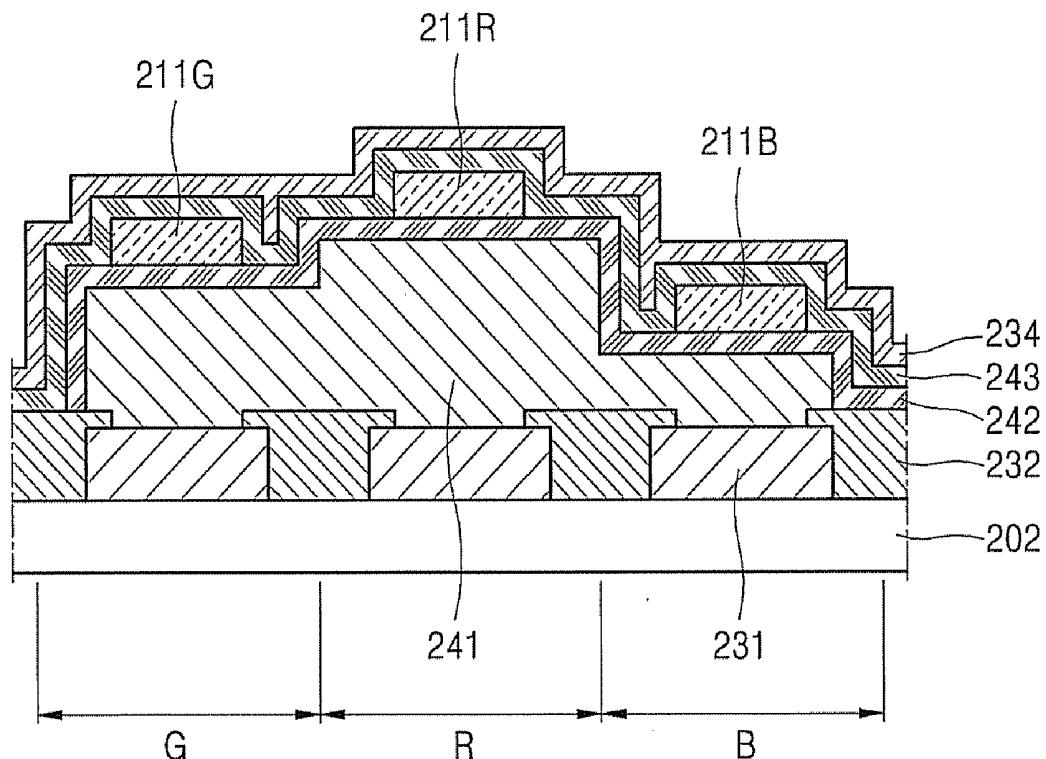


FIG. 7A

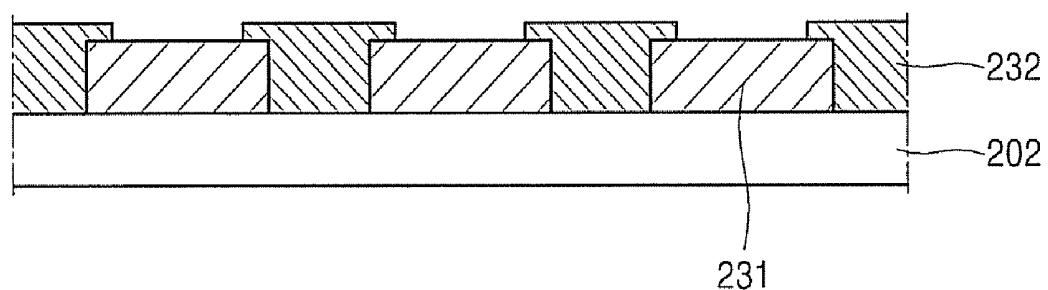


FIG. 7B

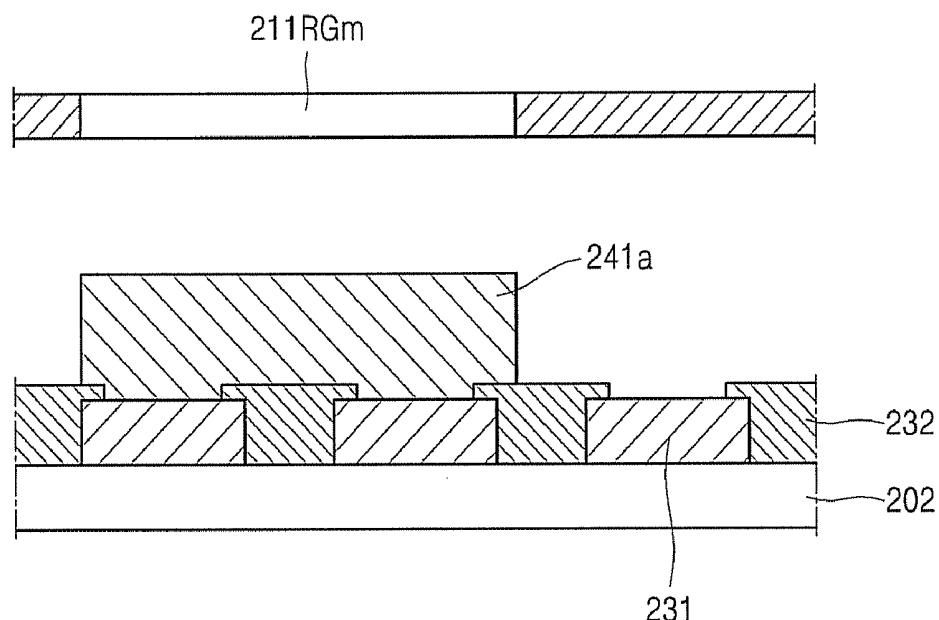


FIG. 7C

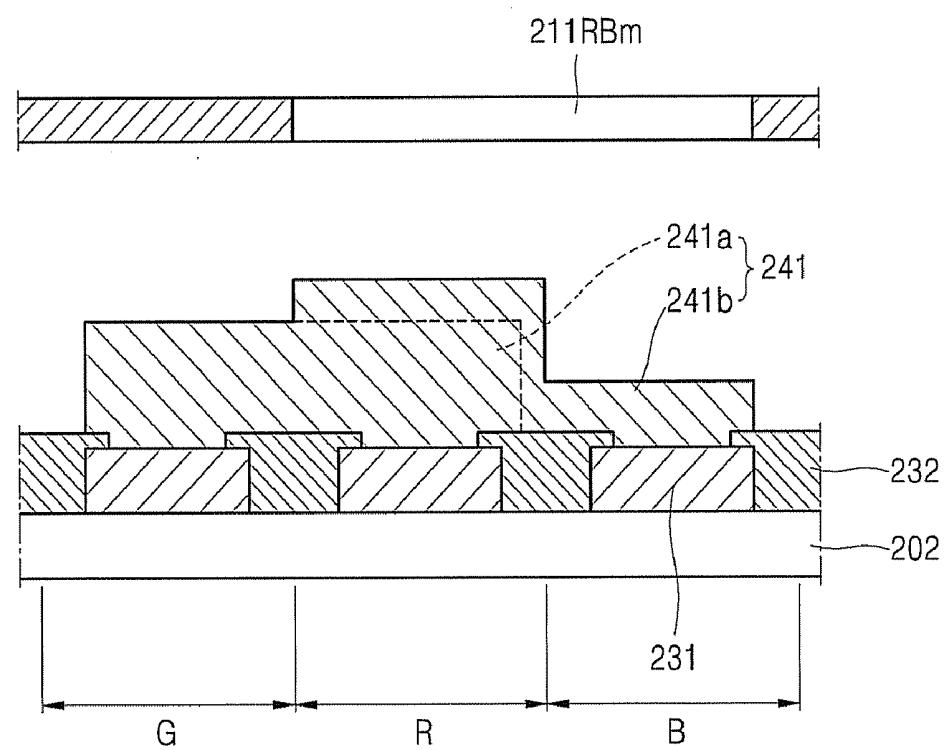


FIG. 7D

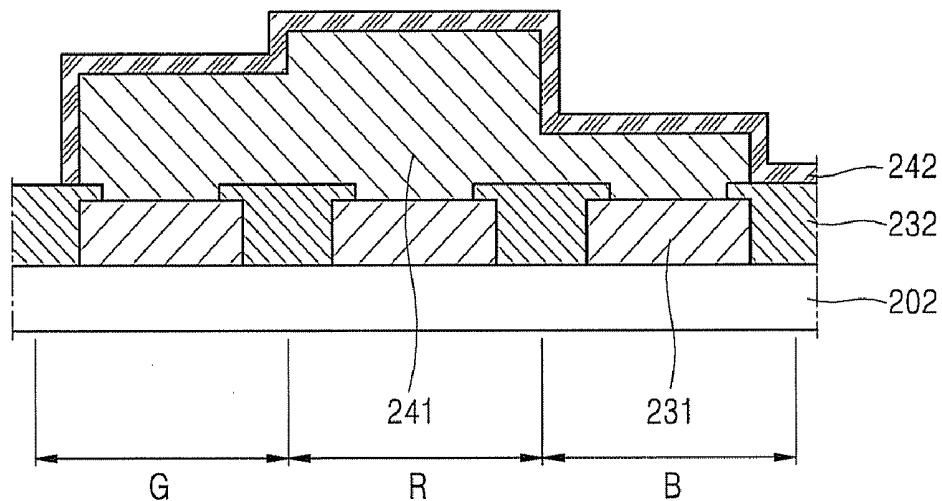


FIG. 7E

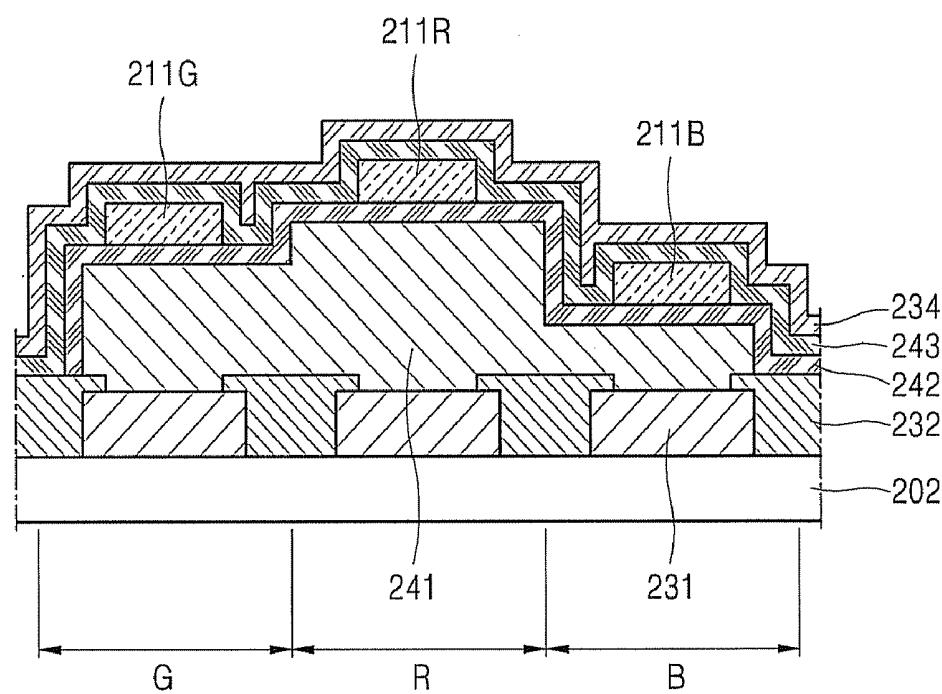


FIG. 8

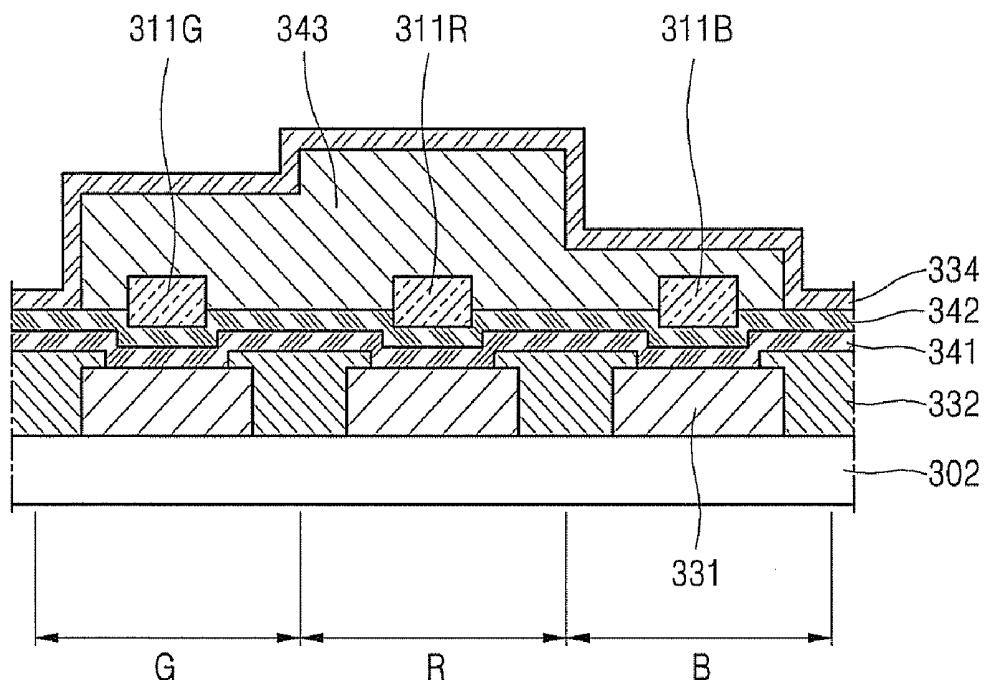


FIG. 9A

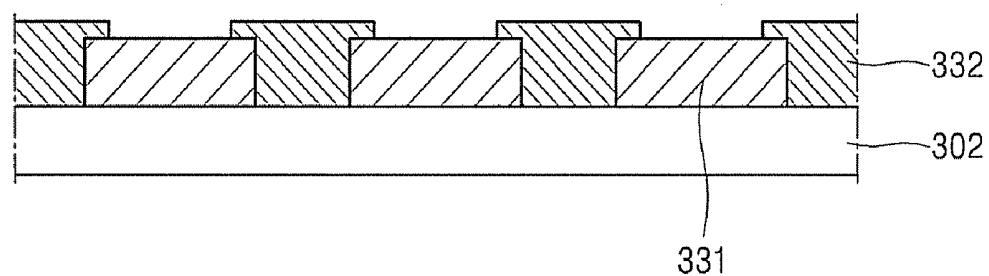


FIG. 9B

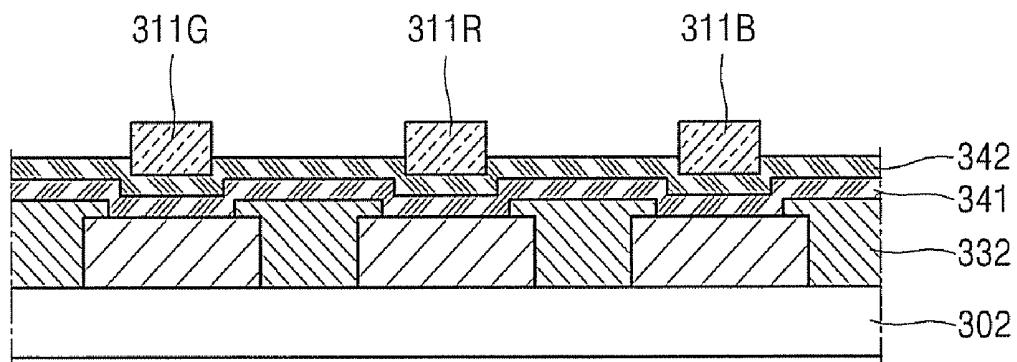


FIG. 9C

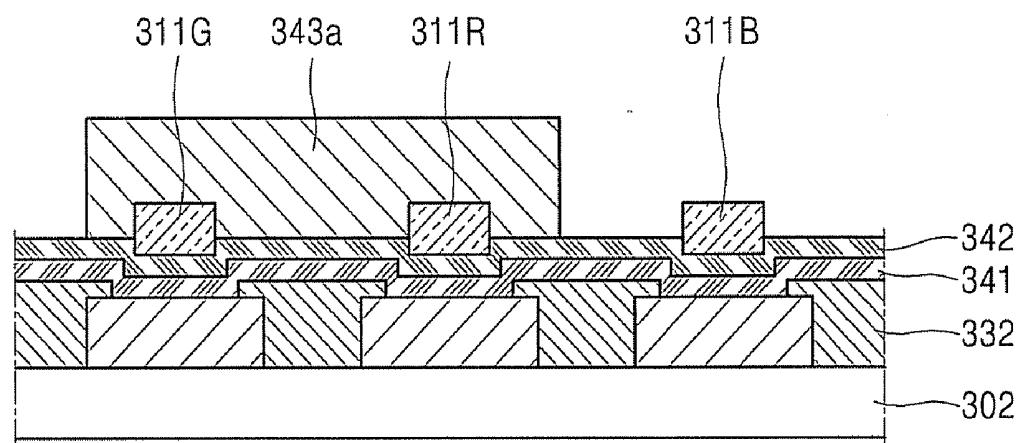
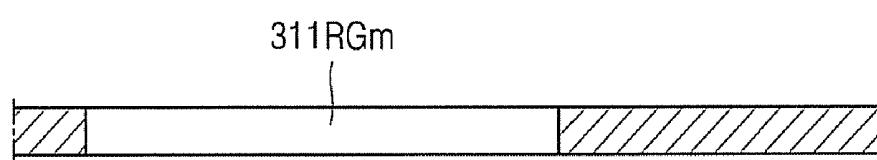


FIG. 9D

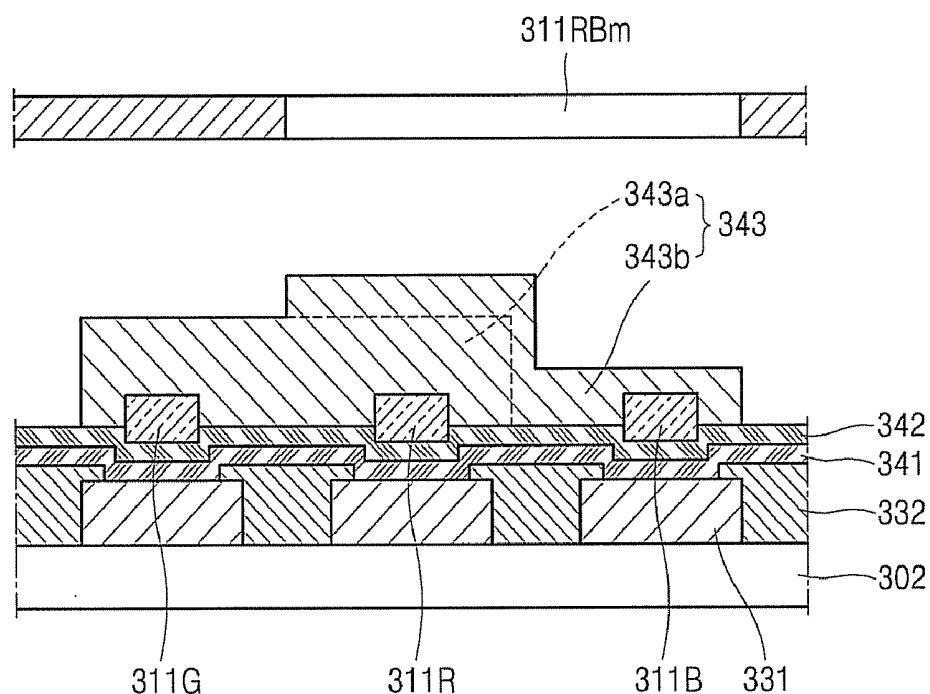


FIG. 9E

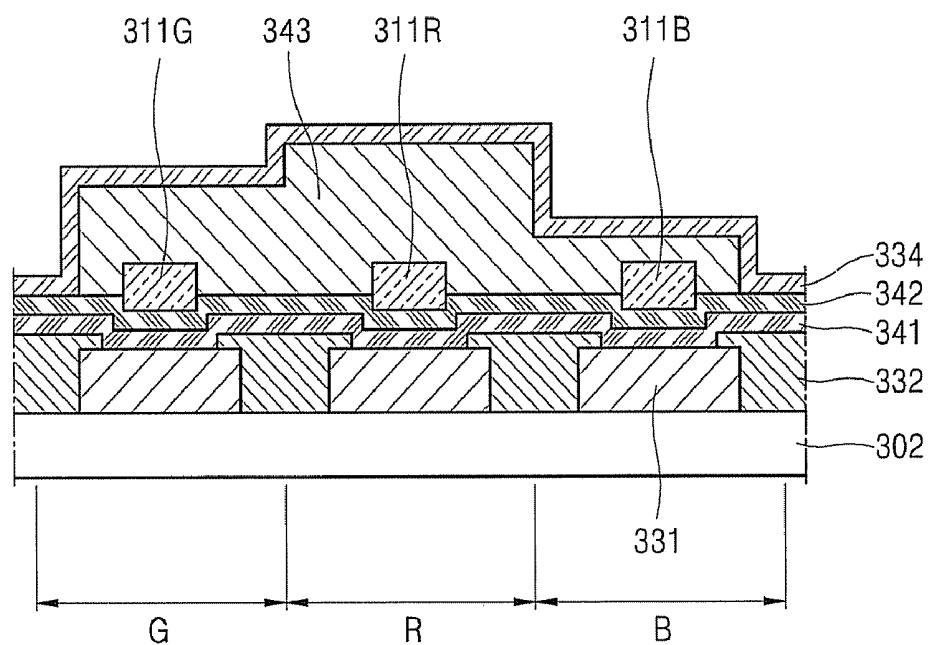


FIG. 10A

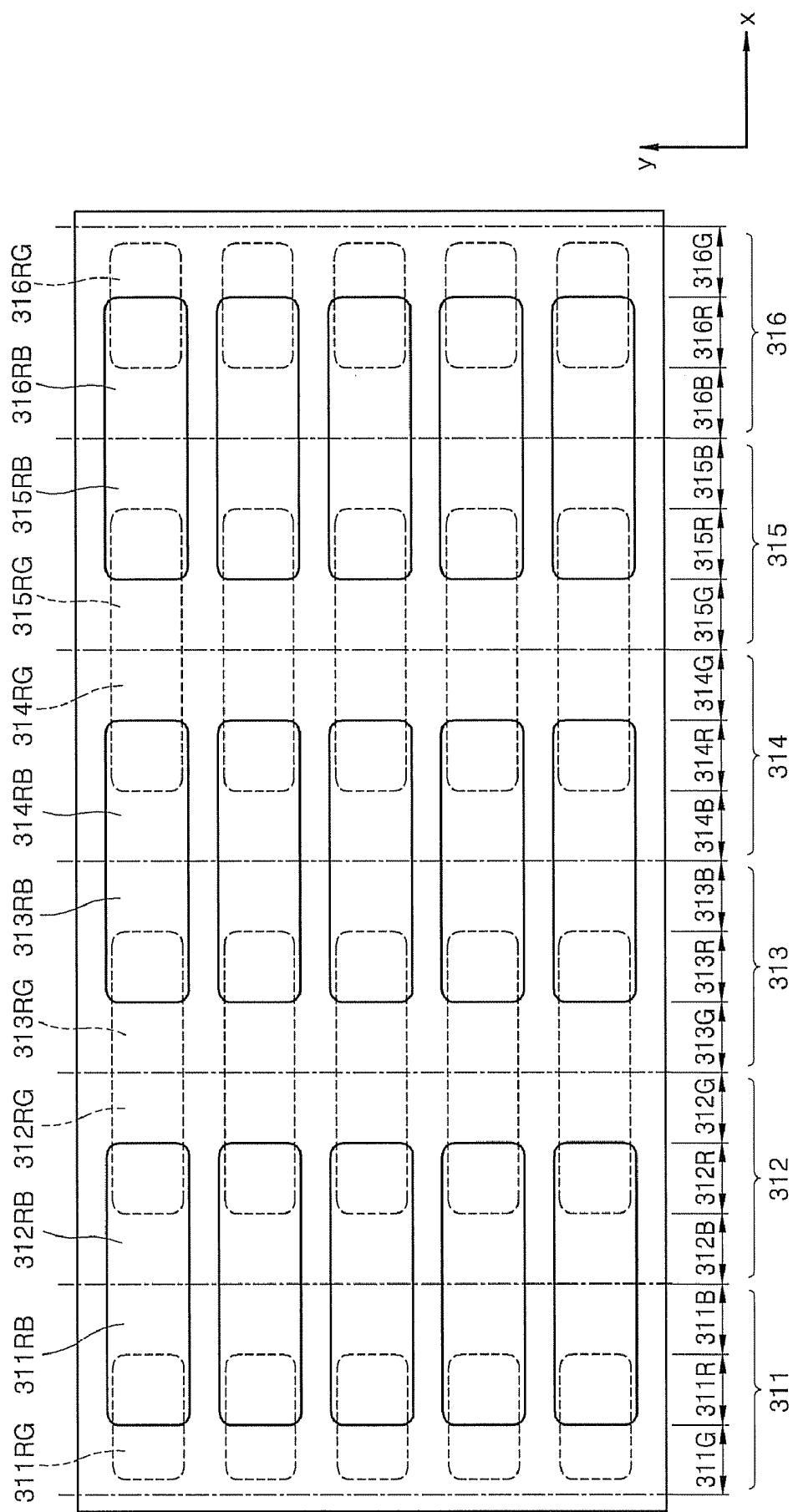


FIG. 10B

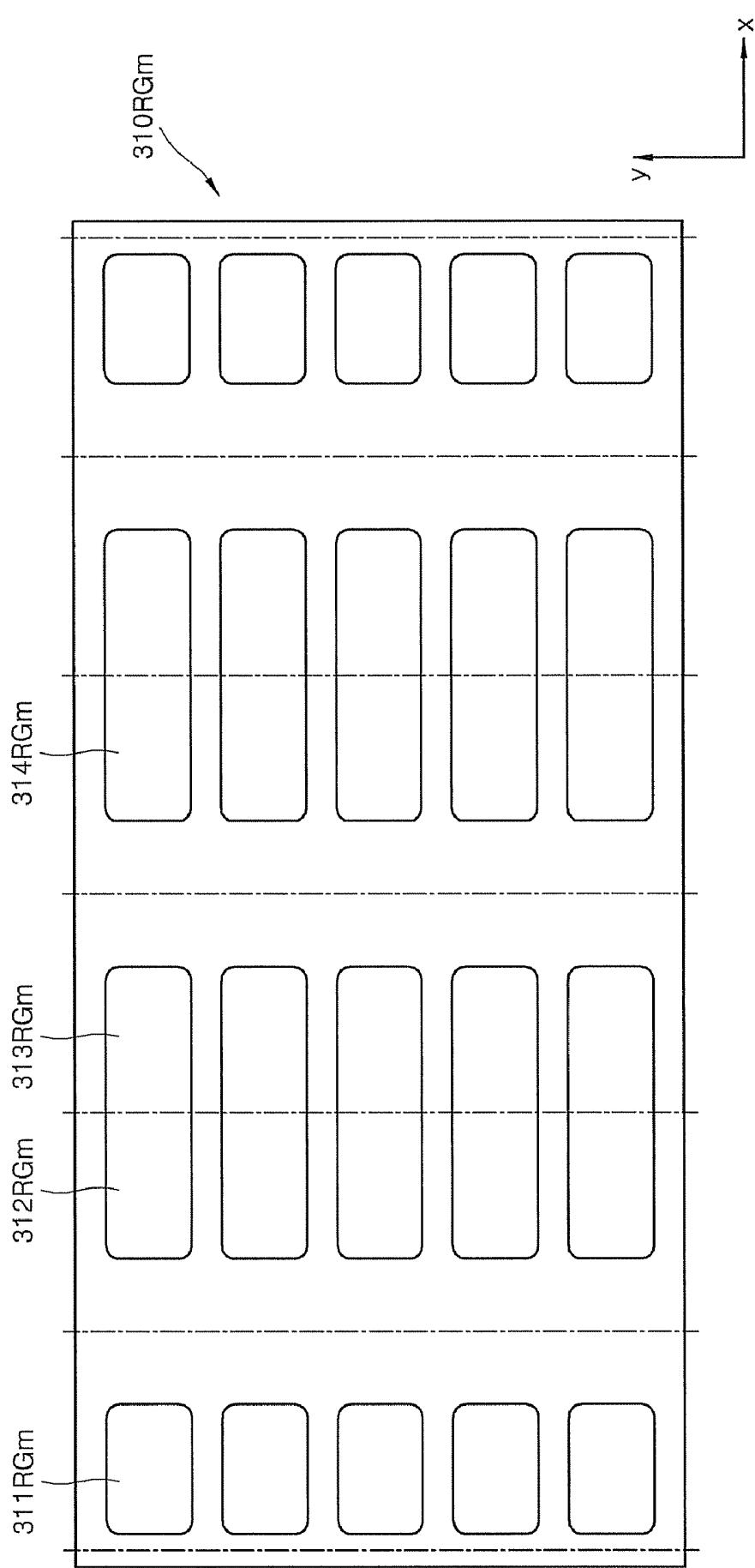


FIG. 10C

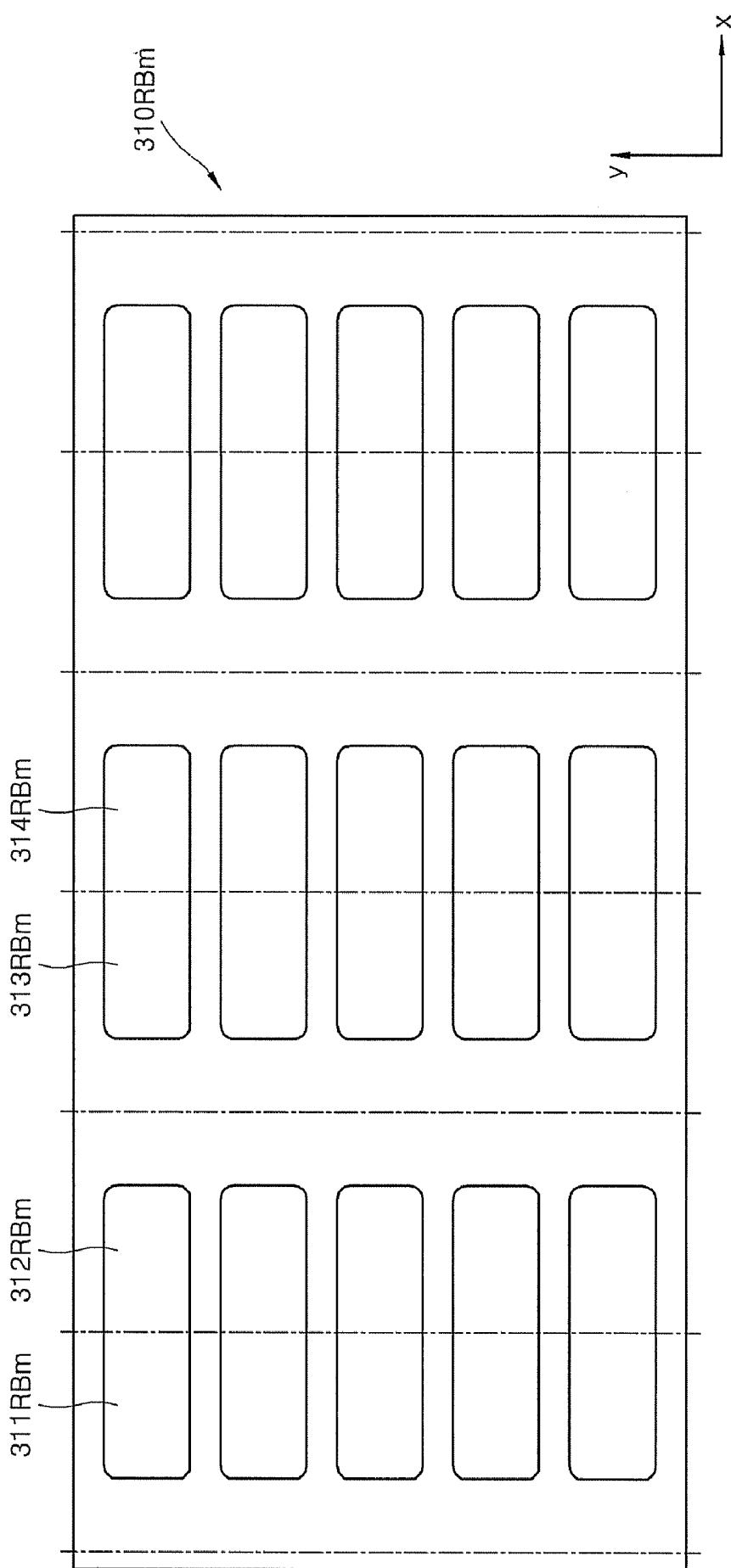


FIG. 11

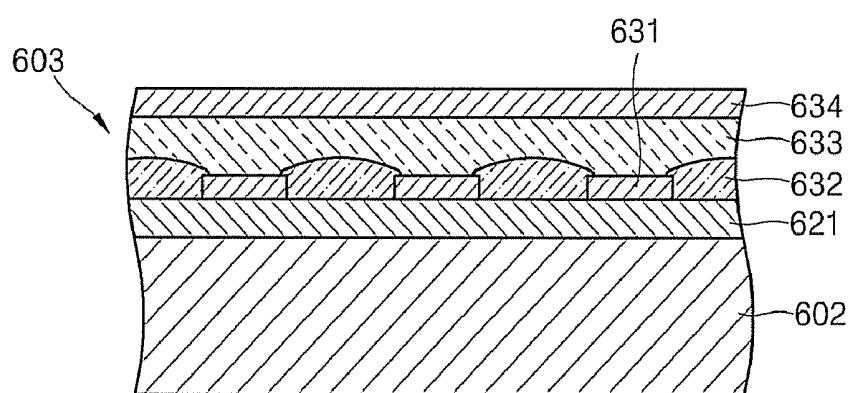
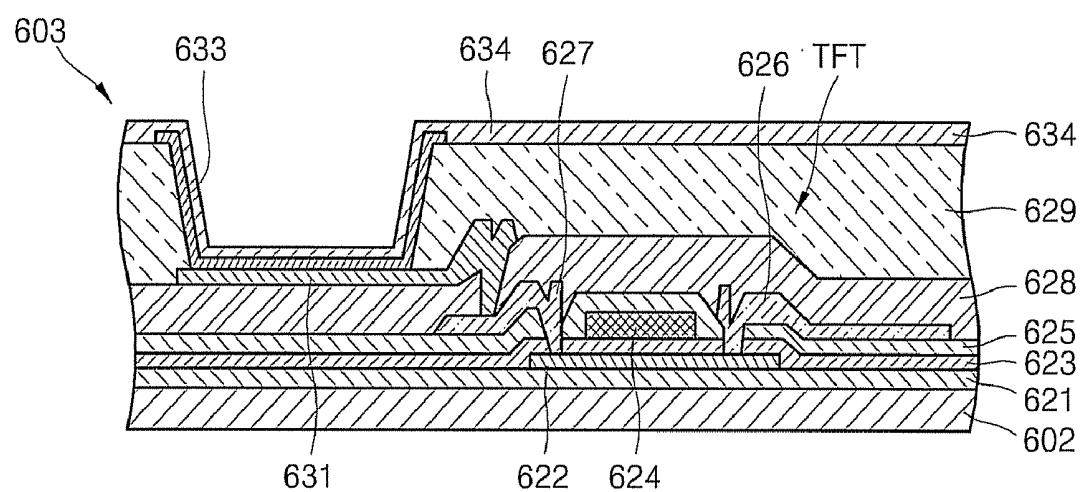


FIG. 12



ORGANIC LIGHT-EMITTING DISPLAY APPARATUS AND METHOD OF MANUFACTURING THE SAME

CROSS-REFERENCE TO RELATED PATENT APPLICATION

[0001] This application claims the priority of Korean Patent Application No. 2008-23413, filed on Mar. 13, 2008, in the Korean Intellectual Property Office, the disclosure of which is incorporated herein in its entirety by reference.

BACKGROUND OF THE INVENTION

[0002] 1. Field of the Invention

[0003] Aspects of the present invention relate to an organic light-emitting display device and a method of manufacturing the same, and more particularly, to an organic light-emitting display device including an easily and precisely deposited intermediate layer, and a method of manufacturing the same.

[0004] 2. Description of the Related Art

[0005] Organic light-emitting display devices are considered to be the next-generation of display devices, since they have a wide viewing angle, a high contrast, and a quick response speed. In general, an organic light-emitting display device has a stacked structure, in which an emission layer is interposed between an anode and a cathode. A color display can thereby be realized, based on a principle that light is emitted, by reuniting holes injected from the anode and electrons injected from the cathode, on the emission layer. However, such a structure makes it difficult to achieve efficient light emission. Thus, intermediate layers, such as an electron injection layer, an electron transport layer, a hole transport layer, and a hole injection layer, are selectively inserted between each of the electrodes and the emission layer.

[0006] However, it is difficult to finely pattern a thin organic layer, such as an emission layer, or an intermediate layer, and the luminous efficiencies of red, green, and blue sub-pixels depend on the organic layers being precisely patterned. Thus, a conventional organic light-emitting display device should be improved, since it is difficult to achieve a desirable driving voltage, current density, brightness, color purity, luminous efficiency, and lifetime.

[0007] An organic light-emitting display device can also be structured to include an emission layer and an intermediate layer, between a first electrode and a second electrode. In this case, the first and second electrodes and the intermediate layer may be fabricated in various ways, e.g., by a deposition method. In order to manufacture an organic light-emitting display device according to the deposition method, a thin layer is formed in a predetermined pattern, by closely adhering a mask, having the same pattern as the thin layer, to a plane on which the thin layer is to be formed, and then depositing a material for the thin layer, on the resultant structure.

[0008] FIG. 1A is a plan view schematically illustrating an emission layer/intermediate layer pattern of a conventional organic light-emitting display device 10. FIG. 1B is a plan view schematically illustrating a mask 10Bm for depositing a blue emission layer of the conventional organic light-emitting display device 10. Referring to FIGS. 1A and 1B, pixels 11, 12, 13, and 14 of the conventional organic light-emitting display device 10 respectively include a plurality of emission layers 11R, 12R, 13R, 14R, 11G, 12G, 13G, 14G, 11B, 12B,

13B, and 14B that emit red, green, or blue light. Three sub-pixels respectively emitting red, green, and blue light form one pixel.

[0009] As described above, the emission layers 11R through 14B of the pixels 11 through 14 are formed through deposition, using a mask. For example, the emission layers of red sub-pixels are simultaneously formed through deposition, the emission layers of green sub-pixels are simultaneously formed through deposition, and then the emission layers of blue sub-pixels are simultaneously formed through deposition. Thus, the conventional mask 10Bm having a plurality of openings 11Bm, 12Bm, 13Bm, and 14Bm, as illustrated in FIG. 1B, is used to obtain a blue emission layer pattern of the conventional organic light-emitting display device 10, as illustrated in FIG. 1A. Also, a mask having a plurality of openings formed at the same intervals as in the conventional mask 10Bm needs to be used, in order to form each red and green emission layer pattern of the organic light-emitting display device 10.

[0010] Since the intermediate layer is also formed in the same pattern as the emission layer, a mask having a plurality of openings formed at the same intervals as in the conventional mask 10Bm needs to be used, in order to obtain an intermediate layer pattern of the organic light-emitting display device 10. However, as the distances between sub-pixels become smaller, in order to manufacture high-definition display devices, the sizes of the openings of the masks become smaller. That is, referring to FIG. 1B, the widths \varnothing of the openings 11Bm through 14Bm become smaller. Thus, a mask having smaller openings is used, in order to realize a high-definition organic light-emitting display device. However, there is a limit as to how fine-pitched a mask can be.

[0011] Also, as a mask pattern becomes finer, it is more difficult to pattern the mask and align the mask with respect to a region on which an emission layer/intermediate layer is to be deposited. Even a slight error may cause an emission layer to overlap an adjacent emission layer. Furthermore, display devices, other than an organic light-emitting display device, manufactured through such deposition, also have the above-described disadvantages.

SUMMARY OF THE INVENTION

[0012] Aspects of the present invention provide a display device, in which an intermediate layer of each sub-pixel can be easily and precisely deposited.

[0013] According to an aspect of the present invention, there is provided an organic light-emitting display device including a plurality of pixels. Each of the pixels comprises a red, a green, and a blue sub-pixel. The display device includes an intermediate layer that is formed to different thicknesses in the respective sub-pixels.

[0014] According to aspects of the present invention, in each pixel, the red sub-pixel may be arranged between the blue and green sub-pixels. The thickness of the intermediate layer may be at a maximum in the red sub-pixels.

[0015] According to aspects of the present invention, the sum of the thickness of the intermediate layer of the green sub-pixel and the thickness of the intermediate layer of the blue sub-pixel may be substantially equal to the thickness of the intermediate layer in the red sub-pixel.

[0016] According to aspects of the present invention, an intermediate layer may be formed as one piece, within each of the pixels.

[0017] According to aspects of the present invention, each of the sub-pixels may further comprise: opposing first and second electrodes; an intermediate layer disposed between the electrodes; and red, green, and blue emission layers disposed within the intermediate layer. The thickness of the intermediate layer in a region having the red emission layer is greater than of at least one of a region having the green emission layer and a region having the blue emission layer.

[0018] According to aspects of the present invention, the sub-pixels included in the adjacent pixels may be arranged such that the respective sub-pixels of a pixel are symmetrical with respect to a boundary between the adjacent pixels.

[0019] According to aspects of the present invention, an intermediate layer may be formed as one piece, and can extend across adjacent pixels.

[0020] According to aspects of the present invention, the intermediate layer may comprise: a hole injection layer formed within each of the pixels to a generally constant thickness; and a hole transport layer formed on the hole injection layer, having a thickness that varies according to the respective sub-pixels.

[0021] According to aspects of the present invention, the intermediate layer may comprise: a hole injection layer having a thickness that varies according to the respective sub-pixels; and a hole transport layer formed on the hole injection layer, having a uniform thickness.

[0022] According to aspects of the present invention, the intermediate layer may comprise: a hole injection layer having a thickness that varies according to the respective sub-pixels; and a hole transport layer formed on the hole injection layer, having a thickness that varies according to the respective sub-pixels.

[0023] According to aspects of the present invention, the intermediate layer may comprise an electron transport layer having a thickness that varies according to the respective sub-pixels.

[0024] According to another aspect of the present invention, there is provided a method of manufacturing an organic light-emitting display device having a plurality of pixels, each having red, green, and blue sub-pixels, the method comprising: forming a plurality of first electrodes on a surface of a substrate; forming an emission layer and an intermediate layer on the first electrode, having a thickness that varies according to the respective sub-pixels; and forming a plurality of second electrodes on the emission layer and the intermediate layer.

[0025] According to aspects of the present invention, the forming of the intermediate layer may comprise: depositing a first portion of the intermediate layer in a first region; and depositing a second portion of the intermediate layer in a second region, which partly overlaps the first region.

[0026] According to aspects of the present invention, the forming of the emission layer may comprise forming a red emission layer in a region where the first region and the second region overlap each other.

[0027] According to aspects of the present invention, the forming of the intermediate layer may comprise: forming the intermediate layer, as one piece, in a region having the red and green sub-pixels; and forming the intermediate layer, as one piece, in a region having the red and green sub-pixels.

[0028] According to aspects of the present invention, the forming of the intermediate layer, as one piece, in the region having the red and green sub-pixels, comprises patterning the

intermediate layer by using a first mask, in which the region having the red and green sub-pixels is formed as one opening.

[0029] According to aspects of the present invention, the forming of the intermediate layer, as one piece, in the region having the red and blue sub-pixels, may comprise patterning the intermediate layer by using a second mask, in which the region having the red and blue sub-pixels is formed as one opening.

[0030] According to aspects of the present invention, the forming of the intermediate layer may comprise forming an intermediate layer, as one piece, within each of the pixels.

[0031] According to aspects of the present invention, the forming of the emission layer and the intermediate layer may comprise: forming an intermediate layer on the first electrode, such that the thickness of a part of the intermediate layer varies according to sub-pixels; and forming an emission layer on the intermediate layer.

[0032] According to aspects of the present invention, the forming of the intermediate layer may comprise: forming a hole injection layer on the first electrode to a generally constant thickness; and forming a hole transport layer on the hole injection layer, such that the thickness of a part of the hole transport layer varies according to sub-pixels.

[0033] According to aspects of the present invention, the forming of the intermediate layer may comprise: forming a hole injection layer on the first electrode, such that the thickness of a part of the hole injection layer varies according to sub-pixels.

[0034] According to aspects of the present invention, the forming of the intermediate layer may comprise: forming a hole injection layer on the first electrode, such that the thickness of the hole injection layer varies according to sub-pixels; and forming a hole transport layer on the hole injection layer, such that the thickness of the hole transport layer varies according to the sub-pixels.

[0035] According to aspects of the present invention, the forming of the emission layer and the intermediate layer may comprise: forming an emission layer on the first electrode; and forming an intermediate layer on the emission layer, such that the thickness of the intermediate layer varies according to sub-pixels.

[0036] According to aspects of the present invention, the forming of the intermediate layer may comprise forming an electron transport layer on the emission layer, such that the thickness of the electron transport layer varies according to sub-pixels.

[0037] According to another aspect of the present invention, there is provided an organic light-emitting display device comprising: a substrate; opposing first and second electrodes disposed on the substrate; and an intermediate layer disposed between the electrodes; and a plurality of emission layers disposed in the intermediate layer. A red emission layer is arranged between blue and green emission layers at the center of one pixel. The thickness of an intermediate layer is at a maximum adjacent to the red emission layer.

[0038] According to aspects of the present invention, the intermediate layer may comprise at least one of a hole injection layer, a hole transport layer, and an electron transport layer.

[0039] According to aspects of the present invention, the intermediate layer may be formed as one piece within each pixel.

[0040] According to aspects of the present invention, the first electrode may be a reflective electrode, and the second electrode may be a semi-transparent electrode, or a transparent electrode.

[0041] According to aspects of the present invention, a resonance may occur between the first electrode and the second electrode, when the device is driven.

[0042] Additional aspects and/or advantages of the invention will be set forth in part in the description which follows and, in part, will be obvious from the description, or may be learned by practice of the invention.

BRIEF DESCRIPTION OF THE DRAWINGS

[0043] These and/or other aspects and advantages of the invention will become apparent and more readily appreciated from the following description of the embodiments, taken in conjunction with the accompanying drawings of which:

[0044] FIG. 1A is a plan view schematically illustrating an emission layer/intermediate layer pattern of a conventional organic light-emitting display device;

[0045] FIG. 1B is a plan view schematically illustrating a conventional mask for depositing a blue emission layer of the organic light-emitting display device of FIG. 1A;

[0046] FIG. 2 is a cross-sectional view of an organic light-emitting display device, according to a first exemplary embodiment of the present invention;

[0047] FIGS. 3A through 3E are cross-sectional views sequentially illustrating a method of manufacturing the organic light-emitting display device, according to the first exemplary embodiment of the present invention;

[0048] FIGS. 4 and 5 are plan views schematically illustrating masks for depositing intermediate layers of an organic light-emitting display device;

[0049] FIG. 6 is a cross-sectional view of an organic light-emitting display device, according to a second exemplary embodiment of the present invention;

[0050] FIGS. 7A through 7E are cross-sectional views sequentially illustrating a method of manufacturing the organic light-emitting display device, according to the second exemplary embodiment of the present invention;

[0051] FIG. 8 is a cross-sectional view of an organic light-emitting display device, according to a third exemplary embodiment of the present invention;

[0052] FIGS. 9A through 9E are cross-sectional views sequentially illustrating a method of manufacturing the organic light-emitting display device according to the third exemplary embodiment of the present invention;

[0053] FIG. 10A is a plan view schematically illustrating an intermediate layer pattern of an organic light-emitting display device, according to a fourth exemplary embodiment of the present invention;

[0054] FIG. 10B is a plan view schematically illustrating a mask for depositing red-green intermediate layers of the organic light-emitting display device of FIG. 10A, according to an exemplary embodiment of the present invention;

[0055] FIG. 10C is a plan view schematically illustrating a mask for depositing red-blue intermediate layers of the organic light-emitting display device of FIG. 10A, according to an exemplary embodiment of the present invention;

[0056] FIG. 11 is a cross-sectional view of a passive matrix (PM) light-emitting device, according to an exemplary embodiment of the present invention; and

[0057] FIG. 12 is a cross-sectional view of an active matrix (AM) light-emitting device, according to an exemplary embodiment of the present invention.

DETAILED DESCRIPTION OF THE EMBODIMENTS

[0058] Reference will now be made in detail to the exemplary embodiments of the present invention, examples of which are illustrated in the accompanying drawings, wherein like reference numerals refer to the like elements throughout. The exemplary embodiments are described below, in order to explain the aspects of the present invention, by referring to the figures. As referred to herein, when a first element is said to be disposed or formed “on”, or “adjacent to”, a second element, the first element can directly contact the second element, or can be separated from the second element by one or more other elements can be located therebetween. In contrast, when an element is referred to as being disposed “directly on” another element, there are no intervening elements present. As used herein, the term “and/or” includes any and all combinations of one or more of the associated listed items.

[0059] FIG. 2 is a cross-sectional view of an organic light-emitting display device, according to a first exemplary embodiment of the present invention. Referring to FIG. 2, the organic light-emitting display device includes a substrate 102, first electrodes 131, an insulating layer 132, second electrodes 134, emission layers (EML) 111R (red emission layer), 111G (green emission layer), and 111B (blue emission layer), and an intermediate layer that is formed on the top and/or bottom of the emission layers 111R, 111G, and 111B. The intermediate layer includes a hole injection layer (HIL) 141, a hole transport layer (HTL) 142, and an electron transport layer (ETL) 143. The emission layers 111R, 111G, and 111B, and the HIL, HTL, and ETL 141, 142, and 143 are formed between the first electrodes 131 and the second electrodes 134. The emission layers 111R, 111G and 111B may emit red, green, or blue light, according to a material thereof, respectively.

[0060] The first electrodes 131 are patterned on the substrate 102. Then, the insulating layer 132 is formed to fill gaps between the first electrodes 131, thus defining pixel regions. The HIL 141, the HTL 142, the emission layers 111R, 111G, and 111B, the ETL 143, and an electron injection layer (EIL) (not shown) are deposited on the first electrodes 131, as a single or a composite structure. Then, the second electrodes 134 are formed on the ETL 143.

[0061] One of the first electrodes 131 or the second electrodes 134 are reflective electrodes and the others are semi-transparent or transparent electrodes. Thus, a resonance may occur between the first electrodes 131 and the second electrodes 134, when the organic light-emitting display device is driven. Thus, light generated by the emission layers 111R, 111G, and 111B, when the organic light-emitting display device is driven, is emitted outside the organic light-emitting display device, while resonating between the first electrode 131 and the second electrode 134. Accordingly, the brightness and efficiency of light emission may be improved.

[0062] More specifically, the first electrodes 131 may be formed on a surface of the substrate 102. In the present exemplary embodiment, the first electrodes 131 may be reflective electrodes, and the second electrodes 134 may be semi-transparent or transparent electrodes. Thus, light generated by the emission layers 111R, 111G, and 111B may be emitted outside the organic light-emitting display device (in

the opposite direction of the substrate **102**), via the second electrodes **134**, while resonating between the first and second electrodes **131** and **134**.

[0063] An intermediate layer of an organic light-emitting display device, according to an exemplary embodiment of the present invention, may include the HIL **141** or the HTL **142**, or may include a single layer having hole injection and transport characteristics.

[0064] The organic light-emitting display device, according to the first exemplary embodiment, is manufactured in such a manner that an intermediate layer including the HIL **141** or the HTL **142** is deposited at different thicknesses on different sub-pixels. More specifically, the HTL **142** may be formed to a thickness of 1600 Å to 2200 Å in a red sub-pixel R. If the thickness of the HTL **142** is less than 1600 Å, or greater than 2200 Å, the emission layer **111R** may not have appropriate hole injection characteristics and/or hole transport characteristics, so as to cause the resonance, and thus, the degree of color purity and the luminous efficiency may be degraded. If the thickness of the HTL **142** is greater than 2200 Å, a driving voltage may increase.

[0065] In a green sub-pixel G, the HTL **142** may be formed to a thickness of 1000 Å to 1200 Å. If the thickness of the HTL **142** is less than 1000 Å, or greater than 1200 Å, the emission layer **111G** may not have appropriate hole injection characteristics and/or hole transport characteristics, to cause the resonance, and thus, the degree of color purity and the luminous efficiency may be degraded. If the thickness of the HTL **142** is greater than 1200 Å, the driving voltage may increase.

[0066] In a blue sub-pixel B, the HTL **142** may be formed to a thickness of 100 Å to 500 Å. If the thickness of the HTL **142** is less than 100 Å, or greater than 500 Å, the emission layer **111B** may not have appropriate hole injection characteristics and/or hole transport characteristics, to cause the resonance, and thus, the degree of color purity and the luminous efficiency may be degraded. If the thickness of the HTL **142** is greater than 500 Å, the driving voltage may increase.

[0067] In the present exemplary embodiment, the HTL **142** is formed, as one piece, in the red sub-pixel R and the green red sub-pixel G, and then is formed again, as one piece, in the red sub-pixel and a blue red sub-pixel B. That is, the HTL **142** is deposited on the green and blue sub-pixels G and B only once, but is deposited on the red sub-pixel R twice. Thus, the thickness of the HTL **142** in the red sub-pixel R is greater than in the green and blue sub-pixels G and B. In other words, the thickness of the HTL **142** in the red sub-pixel R is substantially equal to the sum of the thickness of the HTL **142** in the green sub-pixel G and the thickness of the HTL **142** in the blue sub-pixel B. Also, the HTL **142** is formed as one piece within one pixel.

[0068] As described above, in an organic light-emitting display device, according to an exemplary embodiment of the present invention, resonance may occur between first and second electrodes, when the organic light-emitting display device is driven. In this case, the thickness of a hole transport layer varies, according to the color of light emitted from an emission layer, thereby achieving good driving voltage, current density, brightness of light emission, degree of color purity, luminous efficiency, lifetime, and so on.

[0069] FIGS. 3A through 3E are cross-sectional views schematically and sequentially illustrating a method of manufacturing the organic light-emitting display device, according to the first exemplary embodiment of the present invention. Referring to FIGS. 3A through 3E, the method includes form-

ing the first electrodes **131** on the surface of the substrate **102**, forming the HTL **142** on the first electrodes **131**, so that the thickness of a part of the HTL **142** is greater than that of the remaining part thereof, forming the emission layers **111G**, **111R**, and **111B** on the HTL **142**, and forming second electrodes **134** on the emission layers **111G**, **111R**, and **111B**.

[0070] More specifically, as illustrated in FIG. 3A, the first electrodes **131** are formed on the substrate **102**. The substrate **102** can be any substrate used in the field of general organic light-emitting devices. For example, various types of substrates, such as a glass substrate, or a plastic substrate, can be used, in consideration of transparency, smoothness, tractability, water-resistance, and so on.

[0071] The first electrodes **131** may be reflective electrodes, semi-transparent electrodes, or transparent electrodes formed using a conductive metal material selected from the group consisting of lithium (Li), magnesium (Mg), aluminum (Al), an aluminum-lithium alloy (Al—Li), calcium (Ca), a magnesium-indium alloy (Mg—In), a magnesium-silver alloy (Mg—Ag), and a calcium-aluminum alloy (Ca—Al), or a metal oxide material selected from the group consisting of an indium tin oxide (ITO), an indium zinc oxide (IZO), and an indium oxide (In₂O₃). Otherwise, the first electrodes **131** may be formed using a combination of two or more materials selected from the conductive metals and the metal oxides.

[0072] The insulating layer **132** is formed in a region in which an organic layer is to be formed. The insulating layer **132** can be formed in various ways, including a deposition method or a coating method, using an inorganic substance, such as a silicon oxide and a nitride, or an insulating organic substance.

[0073] As illustrated in FIG. 3B, the HIL **141** is formed on the first electrodes **131** and the insulating layer **132**, to a predetermined thickness. The HIL **141** can be formed by various known methods, including a vacuum deposition method, a spin-coating method, a casting method, or a Langmuir-Blodgett (LB) method.

[0074] As illustrated in FIG. 3C, a first HTL **142a** is formed on the HIL **141**, as one piece, in the red sub-pixel R and the green sub-pixel G. Then, as illustrated in FIG. 3D, a second HTL **142b** is formed on the HIL **141**, as one piece, in the red sub-pixel R and the blue sub-pixel B.

[0075] In detail, as the distances between sub-pixels become smaller, in order to manufacture high-definition display devices, the sizes of openings of a mask for depositing emission layers/intermediate layers of the sub-pixels also becomes smaller. Thus, a fine-pitch mask having smaller openings is used in order to realize a high-definition organic light-emitting display. However there is a limit of the pitch of the mask.

[0076] In order to solve the above problem, according to an embodiment of the present invention, an intermediate layer is deposited, as one piece, in two adjacent sub-pixel regions, i.e., in the red sub-pixel R and the green sub-pixel G, and on the red sub-pixel R, and the blue sub-pixel B.

[0077] The optimal thickness of an intermediate layer varies according to the type of emission layer. The intermediate layer is the thickest at the red sub-pixel R. The green sub-pixel G and the blue sub-pixel B are arranged on either side of the red sub-pixel R. Then, an intermediate layer is formed, as one piece, in the red sub-pixel R and the green sub-pixel G, and then is formed again, as one piece, in the red sub-pixel R and the blue sub-pixel B. That is, the intermediate layer is formed only once in the green sub-pixel G and the blue sub-pixel B,

but is formed twice in the red sub-pixel R. Accordingly, the thickness of the intermediate layer in the red sub-pixel R is greater than in the green and blue sub-pixels G and B. In other words, the thickness of the red sub-pixel R is substantially equal to the sum of the thickness of the intermediate layer in the green sub-pixel G and the thickness of the intermediate layer in the blue sub-pixel B.

[0078] In the method of manufacturing the organic light-emitting display device, according to the first exemplary embodiment, masks 110RGm and 110RBm, as illustrated in FIGS. 4 and 5, are used. When the masks 110RGm and 110RBm are used, the width I1, of each of a plurality of openings 111RGm and 112RGm in the mask 110RGm and a plurality of openings 111RBm and 112RBm in the mask 110RBm, is approximately double the width I0 of each of the openings 11Bm and 12Bm of the conventional mask 10Bm, illustrated in FIG. 1B. Accordingly, it is possible to lessen difficulties in manufacturing and alignment processes of a mask, thereby, increasing the yield and reducing costs in manufacturing a high-quality and high-definition display device.

[0079] As illustrated in FIG. 3E, the emission layers 111R, 111G and 111B are formed on the HTL 142. A material of the emission layers 111R, 111G, and 111B is not particularly limited. Then, the ETL 143 is formed by vacuum-depositing or spin-coating an electron transport material on the emission layers 111R, 111G and 111B. The electron transport material is not particularly limited and may be Alq3. Then, the second electrodes 134 are formed by depositing a material for a second electrode on the ETL 143. The material for a second electrode may be a conductive, transparent, metal oxide selected from the group consisting of indium tin oxide (ITO), indium zinc oxide (IZO), tin oxide (SnO_2), and a zinc oxide (ZnO). Otherwise, the ETL 143 may be formed as a reflective electrode, a semi-transparent electrode, or a transparent electrode, by depositing a thin film using a metallic material selected from the group consisting of lithium (Li), magnesium (Mg), aluminum (Al), an aluminum-lithium alloy (Al—Li), calcium (Ca), a magnesium-indium alloy (Mg—In), a magnesium-silver alloy (Mg—Ag), and a calcium-aluminum alloy (Ca—Al). However, the material for a second electrode is not limited to the described materials. The first electrodes 131 and the second electrodes 134 may respectively function as an anode and a cathode, and vice versa.

[0080] As described above, according to an exemplary embodiment of the present invention, a fine-pitch mask for forming intermediate layers can be easily manufactured, since the sizes of openings of the mask may be relatively large. Thus, a high-definition display device can be manufactured using the mask.

[0081] FIG. 6 is a cross-sectional view of an organic light-emitting display device, according to a second exemplary embodiment of the present invention. FIGS. 7A through 7E are cross-sectional views schematically and sequentially illustrating a method of manufacturing the organic light-emitting display device.

[0082] Referring to FIGS. 6 and 7, the organic light-emitting display device includes a substrate 202, a plurality of first electrodes 231, an insulating layer 232, a plurality of second electrodes 234, a plurality of emission layers 211R (red emission layer), 211G (green emission layer), and 211B (blue emission layer), and an intermediate layer formed on the top and/or bottom of the emission layers 211R, 211G, and 211B. The intermediate layer includes a hole injection layer 241, a

hole transport layer 242, and an electron transport layer 243. The emission layers 211R, 211G, and 211B and the hole injection, hole transport, and electron transport layers 241, 242, and 243 are formed between the first electrodes 231 and the second electrodes 234. The emission layers 211R, 211G, and 211B may respectively emit red, green, or blue light depending on a material thereof.

[0083] The second exemplary embodiment is differs from the first exemplary embodiment in that the hole injection layer 241 is formed to different thicknesses for different sub-pixels. In detail, the hole injection layer 241 is formed, as one piece, in a red sub-pixel R and a green sub-pixel G, and is formed again, as one piece, in the red sub-pixel R and a blue sub-pixel B. That is, the hole injection layer 241 is deposited only once in the green sub-pixel G and the blue sub-pixel B, but is deposited twice in the red sub-pixel R. Thus, the thickness of the hole injection layer 241 in the red sub-pixel R is greater than in the green and blue sub-pixels G and B. In other words, the thickness of the hole injection layer 241 in the red sub-pixel R is substantially equal to the sum of the thickness of the hole injection layer 241 in the green sub-pixel G and the thickness of the hole injection layer 241 in the blue sub-pixel B. The hole injection layer 241 is formed as one piece within one pixel. To this end, as illustrated in FIG. 7A, the first electrodes 231 and an insulating layer 232 are formed on the substrate 202.

[0084] Then, as illustrated in FIG. 7B, a hole injection layer 241a is formed, as one piece, on the first electrodes 231 and the insulating layer 232, in both the red sub-pixel R and the green sub-pixel G. Then, as illustrated in FIG. 7C, a hole injection layer 241b is formed, as one piece, on the first electrodes 231 and the insulating layer 232, in both the red sub-pixel R, and the blue sub-pixel B.

[0085] As illustrated in FIG. 7D, the hole transport layer 242 is formed on the hole injection layer 241. Lastly, as illustrated in FIG. 7E, the emission layers 211R, 211G, and 211B, the electron transport layer 243, and the second electrodes 234 are sequentially formed. As described above, a fine-pitch mask for forming intermediate layers can be easily made, since the sizes of openings can be relatively large, and a high-definition display device can be manufactured using the mask.

[0086] In the first exemplary embodiment, a hole injection layer is formed to a predetermined thickness for one pixel, and a hole transport layer is formed on the hole injection layer. The thickness of the hole transport layer can vary at different sub-pixels. In the second exemplary embodiment, a hole injection layer is formed to different thicknesses in different sub-pixels, and a hole transport layer is formed on the hole injection layer. However, the present invention is not limited thereto. That is, it is possible to derive from the first and second exemplary embodiments an organic light-emitting display device, including a hole injection layer formed to different thicknesses, and a hole transport layer that is formed on the hole injection layer, such that the thickness of the hole transport layer varies in different sub-pixels. FIG. 8 is a cross-sectional view of an organic light-emitting display device, according to a third exemplary embodiment of the present invention. FIGS. 9A through 9E are cross-sectional views sequentially illustrating a method of manufacturing the organic light-emitting display device.

[0087] Referring to FIGS. 8 and 9A through 9E, the organic light-emitting display device includes a substrate 302, a plurality of first electrodes 331, an insulating layer 332, a plu-

rality of second electrodes 334, a plurality of emission layers 311R, 311G, and 311B, and an intermediate layer. The intermediate layer can comprise a hole injection layer 341, a hole transport layer 342, and an electron transport layer 343. The emission layers 311R, 311G, and 311B can be formed within the intermediate layer. The emission layers 311R, 311G, and 311B and the hole injection, hole transport, and electron transport layers 341, 342, and 343 are formed between the first electrodes 331 and the second electrodes 334. The emission layers 311R, 311G, and 311B can respectively emit red, green, or blue light, depending on a material thereof.

[0088] The third exemplary embodiment is differentiated from the first and second embodiments, in that the electron transport layer 343 is formed to different thicknesses for different sub-pixels. In detail, the electron transport layer 343 is deposited, as one piece, in both a red sub-pixel R and a green sub-pixel G and then, is deposited, as one piece, in both the red sub-pixel R and a blue sub-pixel B. That is, the electron transport layer 343 is deposited only once in the green and blue sub-pixels G and B, but is deposited twice in the red sub-pixel R. Thus, the thickness of the electron transport layer 343 in the red sub-pixel R is greater than in the green and blue sub-pixels G and B. In other words, the thickness of the electron transport layer 343 in the red sub-pixel R is substantially equal to the sum of the thickness of the electron transport layer 343 in the green sub-pixel G and the thickness of the electron transport layer 343 in the blue sub-pixel B. The electron transport layer 343 is formed as one piece within one pixel.

[0089] As illustrated in FIG. 9A, the first electrodes 331 and the insulating layer 332 are formed on the substrate 302. Then, as illustrated in FIG. 9B, the hole injection layer 341 and the hole transport layer 342 are formed on the first electrodes 331 and the insulating layer 332. The emission layers 311R, 311G, and 311B are formed on the hole transport layer 342. Then, as illustrated in FIG. 9C, an electron transport layer 343a is formed, as one piece, in the red sub-pixel R and the green sub-pixel G.

[0090] As illustrated in FIG. 9D, an electron transport layer 343b is formed, as one piece, in the red sub-pixel R and the blue sub-pixel B. Then, as illustrated in FIG. 9E, the second electrodes 334 are formed on the electron transport layer 343.

[0091] As described above, according to an exemplary embodiment of the present invention, a fine-pitch mask for forming intermediate layers can be easily made, since the sizes of openings can be relatively large, and a high-definition display device can be manufactured using the mask.

[0092] FIG. 10A is a plan view of an intermediate layer pattern of an organic light-emitting display device, according to a fourth exemplary embodiment of the present invention. FIG. 10B is a plan view schematically illustrating a mask for depositing red-green intermediate layers of the organic light-emitting display device of FIG. 10A. FIG. 10C is a plan view schematically illustrating a mask for depositing red-blue intermediate layers of the organic light-emitting display device of FIG. 10A. As described above, FIG. 10A schematically illustrates the intermediate layer pattern of the organic light-emitting display device, but may be considered to represent a plurality of sub-pixels, for convenience of explanation.

[0093] The organic light-emitting display device includes a plurality of pixels, each including red, green, and blue sub-pixels sequentially arranged in one direction, e.g., in the x-axis direction, as indicated in FIG. 10A. The sub-pixels are

arranged such that the colors of the light emitted from the respective sub-pixels of a first pixel are symmetrical with the colors emitted from corresponding sub-pixels of a second pixel facing the first pixel in the x-axis direction, about the boundary between the first and second pixels. That is, for example, the sub-pixels of the pixels in the x-axis direction are arranged in the order of green, red, blue, blue, red, green, green, red, blue, blue, red, green, etc.

[0094] The organic light-emitting display device according to the fourth exemplary embodiment is different from the first and second exemplary embodiments, in terms of an intermediate layer shape. Each of the sub-pixels includes a first electrode and a second electrode that face each other and an intermediate layer interposed between the first and second electrodes. In the organic light-emitting display device, according to the fourth exemplary embodiment, an intermediate layer is formed as one piece, across two sub-pixels that are adjacent in the x-axis direction. More specifically, in the intermediate layer pattern (sub-pixel pattern) illustrated in FIG. 10A, if the plurality of pixels in the uppermost row are a first pixel 311, a second pixel 312, a third pixel 313, and a fourth pixel 314 in the x-axis direction, the first pixel 311 includes a sub-pixel 311G (green sub-pixel), a sub-pixel 311R (red sub-pixel), and a sub-pixel 311B (blue sub-pixel).

[0095] A plurality of sub-pixels 312B, 312R, and 312G of the second pixel 312, which is adjacent to the first pixel 311, are arranged to be symmetrical with respect to the sub-pixels 311G, 311R, and 311B of the first pixel 311, along the boundary between the first and second pixels 311 and 312. Thus, the second pixel 312 includes the sub-pixel 312B, the sub-pixel 312R, and the sub-pixel 312G.

[0096] In the above intermediate layer pattern, an intermediate layer is formed as one piece, in sub-pixels adjacent at the boundary between the first and second pixels 311 and 312. That is, an intermediate layer 311RB is formed as one piece across red and blue sub-pixels 311R and 311B of the first pixel 311. An intermediate layer 312RB is formed as one piece across red and blue sub-pixels 312R and 312B of the second pixel 312. Similarly, an intermediate layer is formed as one piece across sub-pixels adjacent to the boundary between the second pixel 312 and the third pixel 313. That is, an intermediate layer 312RG is formed as one piece for red and green sub-pixels. An intermediate layer 313RG is formed as one piece across red and green sub-pixels in the third pixel 313. Similarly, the other pixels in the x-axis direction also have the above-described pattern.

[0097] In this case, a mask 310RGm illustrated in FIG. 10B is used to form an intermediate layer for red and green sub-pixels. A mask 310RBm illustrated in FIG. 10C is used to form an intermediate layer for red and blue sub-pixels. Referring to FIGS. 10B and 10C, the sizes of openings in the masks 310RGm and 310RBm are relatively large.

[0098] The mask 310RGm illustrated in FIG. 10B is used to deposit an intermediate layer according to the arrangement of sub-pixels in the organic light-emitting display device. The area of each of the openings in the mask 310RGm is approximately four times larger than the openings in the conventional mask 10Bm illustrated in FIG. 1B. Accordingly, a high-definition organic light-emitting display device can be realized.

[0099] The construction of a light-emitting device having the above intermediate layers, which can be included in the organic light-emitting display devices according to the above embodiments, will now be briefly described with reference to FIGS. 11 and 12. A light-emitting device that can be included

in the organic light-emitting display devices is formed on a substrate **602**. The substrate **602** is manufactured using a transparent glass material, but may be manufactured using various plastic materials, such as acryl, polyimide, polycarbonate, polyester, and MYLAR.

[0100] The light-emitting device may have various shapes. For example, the light-emitting device may be a passive matrix (PM) light-emitting device, or may be an active matrix (AM) light-emitting device that has a thin transistor.

[0101] FIG. 11 is a cross-sectional view of a PM light-emitting device **603**, according to an exemplary embodiment of the present invention. Referring to FIG. 6, a buffer layer **621** (SiO_2 layer) is formed on the substrate **602**. A plurality of first electrodes **631** are formed in a predetermined pattern on the buffer layer **621**. Then, an emission layer **633** and a plurality of second electrodes **634** are sequentially formed on the first electrodes **631**. An insulating layer **632** may be interposed between lines of the first electrodes **631**. The second electrodes **634** may be formed in a pattern orthogonal to the pattern of the first electrodes **631**. Although not shown in the drawings, an additional insulating layer may further be included as a pattern orthogonal to the first electrodes **631**, in order to obtain the pattern of the second electrodes **634**.

[0102] The emission layer **633** may be formed of an organic material or an inorganic material. When the emission layer **633** is formed of an organic material, a small molecule organic material, or a polymer organic material, may be used. If a small molecule organic material is used, a hole injection layer (HIL), a hole transport layer (HTL), an organic emission layer (EML), an electron transport layer (ETL), and an electron injection layer (EIL) may be stacked in a single or composite structure. Various organic materials, such as copper phthalocyanine (CuPc), N,N'-Di(naphthalene-1-yl)-N,N'-diphenyl-benzidine (NPB), and tris-8-hydroxyquinoline aluminum (Alq3), can be used. The emission layer **633** is obtained by patterning one of the above small molecule organic materials, and vacuum-depositing the resultant structure using one of the above masks.

[0103] In general, if the emission layer **633** is formed of a polymer organic material, it includes the hole transport layer and the emission layer. In this case, the hole transport layer is formed of Poly(3,4-ethylenedioxythiophene)poly(styrene-sulfonate) (PEDOT), and the emission layer is formed of a Poly-Phenylenevinylene (PPV)/Polyfluorene-based polymer organic material.

[0104] The first electrodes **631** can be anode electrodes, and the second electrodes **634** can be cathode electrodes, and vice versa. The first electrodes **631** may be transparent electrodes or reflective electrodes. If the first electrodes **631** are transparent electrodes, ITO, IZO, ZnO , or In_2O_3 may be used. If the first electrodes **631** are reflective electrodes, first electrodes **631** are obtained by forming a reflective layer, by using Ag, Mg, Al, Pt, Pd, Au, Ni, Nd, Ir, Cr, or a compound thereof and then depositing a layer made of ITO, IZO, ZnO , or In_2O_3 on the resultant structure.

[0105] The second electrodes **634** may also be transparent electrodes or reflective electrodes. If the second electrodes **634** are transparent electrodes, the second electrodes **634** can be used as cathode electrodes. Thus, the second electrodes **634** may be obtained by depositing a metal material having a small work function, such as Li, Ca, LiF/Ca, LiF/Al, Al, Mg, or a compound thereof on the emission layer **633**, which is an organic layer. Auxiliary electrodes or a butt electrode lines can be then formed by using a material, such as ITO, IZO,

ZnO , or In_2O_3 . If the second electrodes **634** are reflective electrodes, they can be formed by depositing Li, Ca, LiF/Ca, LiF/Al, Al, Mg, or a compound thereof.

[0106] FIG. 12 is a cross-sectional view of an AM light-emitting device **603**, according to an exemplary embodiment of the present invention. In the AM light-emitting device **603**, each sub-pixel includes at least one thin film transistor (TFT), as illustrated in FIG. 12. The construction of the TFT is not limited to the one illustrated in FIG. 12, and a total number and construction of thin transistors TFT can vary.

[0107] As illustrated in FIG. 12, a buffer layer **621** made of SiO_2 is formed on a glass substrate **602**, and the TFT is formed on the buffer layer **621**. The TFT includes an active layer **622** on the buffer layer **621**, a gate insulating layer **623** on the active layer **622** and the buffer layer **621**, and a gate electrode **624** on the gate insulating layer **623**. The gate electrode **624** is formed at a predetermined location, on the gate insulating layer **623**, and is connected to a gate line that transfers an on/off signal of the TFT. The predetermined location on which the gate electrode **624** is formed corresponds to a channel region in the active layer **622**.

[0108] An inter-insulator **625** is formed on the gate electrode **624**. A source electrode **626** and a drain electrode **627** are formed to respectively contact a source region and a drain region of the active layer **622**, via a contact hole.

[0109] A passivation layer **628** made of SiO_2 is formed on the source electrode **626** and the drain electrode **627**. A pixel defining layer **629** made of acryl or polyimide is formed on the passivation layer **628**, and can protect the TFT, and also can planarize an upper surface of the TFT.

[0110] Although not shown in the drawings, at least one capacitor is connected to the TFT. A circuit having such the TFT is not limited to the one illustrated in FIG. 12.

[0111] The AM light-emitting device **603** is connected to the drain electrode **627** of the TFT. A first electrode **631** of the AM light-emitting device is formed on the passivation layer **628**, and the pixel defining layer **629** is formed on the first electrode **631**. An emission layer **633** is formed in an opening of the pixel defining layer **629**. FIG. 12 illustrates that the emission layer **633** is patterned to correspond to only one sub-pixel, in order to explain the construction of each of the sub-pixels, for convenience, but the emission layer **633** may extend to an adjacent sub-pixel.

[0112] Materials of the first electrode **631** a second electrode **634**, the emission layer **633**, and intermediate layers (not shown) formed on the top and bottom of the emission layer **633** may be the same as in the PM light-emitting device **603**. The AM light-emitting device **603** is sealed on the substrate **602** an opposite unit (not shown). The opposite unit may include a glass or plastic material, or may be formed as a metal cap.

[0113] In a light-emitting display device having such light-emitting devices, intermediate layers are constructed as described above, and thus, pattern precision can be improved, while easily depositing an intermediate layer in each sub-pixel, thereby increasing the resolution of the light-emitting display device.

[0114] The above exemplary embodiments of the present invention have been described with respect to a light-emitting display device, but aspects of the present invention can also be applied to any type of a display device, in which each sub-pixel is formed through deposition. A display device according to the above embodiments of the present invention has the following advantages.

[0115] First, it is possible to lessen difficulties in manufacturing and alignment processes of a mask. Thus, it is possible to prevent the yield from decreasing, due to a reduction in the distances between sub-pixels. It is also possible to reduce manufacturing costs when manufacturing a high-quality and high definition display device. Second, it is possible to increase the sizes of openings in a mask for forming intermediate layers. Third, it is possible to easily make a fine-pitch mask, and manufacture a high-definition display device by using the mask.

[0116] Although a few embodiments of the present invention have been shown and described, it would be appreciated by those skilled in the art that changes may be made in this embodiment without departing from the principles and spirit of the invention, the scope of which is defined in the claims and their equivalents.

What is claimed is:

1. An organic light-emitting display device comprising:
pixels to emit light in a first direction, comprising a first electrode, a second electrode, and an intermediate layer disposed between the first and second electrodes, wherein,
each pixel is divided into red, green, and blue sub-pixels, and
the thickness of the intermediate layer varies according to the sub-pixels.

2. The device of claim 1, wherein:
in each of the pixels the red sub-pixel is disposed between the green and blue sub-pixels; and
the thickness of the intermediate layer is at a maximum in the red sub-pixel.

3. The device of claim 2, wherein the sum of the thicknesses of the intermediate layer in the blue and green sub-pixels is substantially equal to the thickness of the intermediate layer in the red sub-pixel.

4. The device of claim 1, wherein in each of the pixels the intermediate layer is formed as one piece.

5. The device of claim 1, wherein the red, green, and blue sub pixels respectively comprise red, green, and blue emission layers disposed in the intermediate layer,
wherein the thickness of the intermediate layer is at a maximum in the red sub-pixels.

6. The device of claim 1, wherein the sub-pixels of adjacent pixels are symmetrically disposed according to color, about a boundary between the adjacent pixels.

7. The device of claim 6, wherein the intermediate layer is formed as one or more pieces that each extends across the boundary, so as to be disposed at least two of the adjacent pixels.

8. The device of claim 1, wherein the intermediate layer comprises:

a hole injection layer disposed on the first electrode, having a generally constant thickness; and
a hole transport layers disposed on the hole injection layer, having thicknesses that vary according to the sub-pixels.

9. The device of claim 1, wherein the intermediate layer comprises:

hole injection layers disposed on the first electrode in each pixel, having thicknesses that vary according to the sub-pixels; and
a hole transport layer disposed on the hole injection layers, having a generally constant thickness.

10. The device of claim 1, wherein the intermediate layer comprises:

hole injection layers having thicknesses that vary according to the sub-pixels; and
hole transport layers formed on the hole injection layers, having thicknesses that vary according to the sub-pixels.

11. The device of claim 1, wherein the intermediate layer comprises electron transport layers having thicknesses that vary according to the sub-pixels.

12. A method of manufacturing an organic light-emitting display device having a plurality of pixels that are each divided into red, green, and blue sub-pixels, the method comprising:

forming first electrodes on a surface of a substrate;
forming emission layers and an intermediate layer on the first electrodes, such that the thickness of the intermediate layer varies according to the sub-pixels; and
forming a second electrode on the intermediate layer.

13. The method of claim 12, wherein the forming of the intermediate layer comprises:

forming a first portion of the intermediate layer in a first region; and
forming a second portion of the intermediate layer in a second region that overlaps the first region.

14. The method of claim 13, wherein the forming of the emission layer comprises forming a red emission layer where the first region and the second region overlap.

15. The method of claim 12, wherein the forming of the intermediate layer comprises:

forming first portions of the intermediate layer across adjacent red and green sub-pixels; and
forming second portions of the intermediate layer across adjacent green and red sub-pixels, such that the first and second portions are joined together.

16. The method of claim 15, wherein the forming of first portions of the intermediate layer comprises: using a first mask having openings that correspond to each of the first portions, to pattern the first portions.

17. The method of claim 15, wherein the forming of the second portions of the intermediate layer comprises using a second mask having openings that correspond to each of the second portions, to pattern the second portions.

18. The method of claim 12, wherein the forming of the intermediate layer comprises, in each of the pixels, forming the intermediate layer as one piece.

19. The method of claim 12, wherein the forming of the emission layers and the intermediate layer comprises forming the emission layers within the intermediate layer.

20. The method of claim 19, wherein the forming of the intermediate layer comprises:

forming a hole injection layer on the first electrodes, to a generally constant thickness; and
forming hole transport layers on the hole injection layer, such that the thicknesses of the hole transport layers vary according to the sub-pixels.

21. The method of claim 19, wherein the forming of the intermediate layer comprises:

forming hole injection layers on the first electrode, such that the thicknesses of the hole injection layers vary according to the sub-pixels; and
forming a hole transport layer on the hole injection layers, to a generally constant thickness.

22. The method of claim 19, wherein the forming of the intermediate layer comprises:

forming hole injection layers on the first electrodes, such that the thicknesses of the hole injection layers vary according to the sub-pixels; and

forming hole transport layers on the hole injection layers, such that the thicknesses of the hole transport layers vary according to the sub-pixels.

23. The method of claim 12, wherein the forming of the emission layer and the intermediate layer comprises:

forming a first portion of the intermediate layer on the first electrodes;

forming the emission layers on the first portion;

forming a second portion of the intermediate layer on the emission layers, such that the thickness of the second portion varies according to the sub-pixels.

24. The method of claim 23, wherein the second portion is an electron transport layer.

25. An organic light-emitting display device comprising:
a substrate;
pixels disposed on the substrate and divided into red, green, and blue sub-pixels, the pixels comprising:
a first electrode;
a second electrode; and
an intermediate layer disposed between the first electrode and the second electrode, having a thickness that varies according to the sub-pixels; and

red, green, and blue emission layers disposed within the intermediate layer, in the red, green, and blue sub-pixels, respectively, wherein,

the red sub-pixels are disposed between the blue and green sub-pixels, and

the thickness of the intermediate layer is at a maximum in the red sub-pixels.

26. The device of claim 25, wherein the intermediate layer comprises a hole injection layer, a hole transport layer, and an electron transport layer.

27. The device of claim 25, wherein in each of the pixels the intermediate layer is formed as one piece.

28. The device of claim 25, wherein the first electrode is reflective, and the second electrode is semi-transparent or transparent.

29. The device of claim 25, wherein a resonance occurs between the first electrode and the second electrode when light is emitted from the emission layers.

30. The device of claim 1, wherein the green or blue sub-pixels of adjacent pixels are disposed at a boundary between the adjacent pixels.

31. The device of claim 1, wherein the thickness of the intermediate layer increases from the blue sub-pixel, to the green sub-pixel, to the red sub-pixel.

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专利名称(译) 有机发光显示装置及其制造方法

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摘要(译)

一种有机发光显示装置及其制造方法，所述有机发光显示装置包括包含相对的第一和第二电极的像素，以及设置在所述第一和第二电极之间的中间层。像素被分成红色，绿色和蓝色子像素。中间层具有根据子像素而变化的厚度。

